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CANADIAN THESES ON MICROFICHE

THÈSES CANADIENNES . SUR MICROFICHE

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	YSTAL ELECTRICAL REISTIVITIES
IN CADMIUM	
UNIVERSITY/UNIVERSITÉ UNIVERS	ITY OF ALBERTA.
DEGREE FOR WHICH THESIS WAS PRESENTED! GRADE POUR LEQUEL CETTE THESE FUT PRÉSENTÉE.	Ph. D.
YEAR THIS DEGREE CONFERRED/ANNÉE D'OBTENTION DE CE GRADE	1977
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THE UNIVERSITY OF ALBERTA

SINGLE CRYSTAL ELECTRICAL RESISTIVITIES .

OF CADMIUM AND CADMIUM-MAGNESIUM ALLOYS

by



BRIAN JEFFREY STACKHOUSE

A THESIS

SUBMITTED TO THE FACULTY OF GRADUATE STUDIES AND RESEARCH
IN PARTIAL FULFILLMENT OF THE REQUIREMENTS FOR THE DEGREE
OF DOCTOR OF PHILOSOPHY

IN

PHYSICS

DEPARTMENT OF PHYSICS

EDMONTON, ALBERTA

FALL, 1977

THE UNIVERSITY OF ALBERTA FACULTY OF GRADUATE STUDIES AND RESEARCH

The undersigned certify that they have read, and recommend to the Farilty of Graduate Studies and Research, for acceptance, a thesis entitled SINGLE CRYSTAL ELECTRICAL RESISTIVITIES OF CADMIUM AND CADMIUM-MAGNESIUM ALLOYS submitted by Brian Jeffrey Stackhouse in partial fulfillment of the requirements for the degree of Doctor of Philosophy in Physics.

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ABSTRACT

We have measured the electrical resistivities from 2 K to 300 K for eight Cd single crystals and twelve . Cd-Mg single crystals including three different concentrations. The measured densities of our specimens were typically 2½% below the accepted x-ray densities. This we attribute to small bubbles in the specimens and we have made an appropriate correction to obtain the resistivity values. The ice point resistivities for Cd were found to be ρ_{\parallel} = $7.81(\pm 0.03)\mu\Omega$ cm and ρ_{\perp} = $6.30(\pm 0.03)\mu\Omega$ cm. The resistivity anisotropy ratio α = ρ_{\parallel} / ρ_{\perp} was obtained for both Cd and the most dilute alloy at all temperatures and compared to theoretical models.

Deviations from Natthiessen's rule Δ which were also calculated from these measurements both confirm and clarify earlier experimental results for polycrystalline specimens and agree qualitatively with a theoretical calculation for single crystals. A contribution to Δ appearing above Δ 200 K has all the salient features expected for electron scattering from a local phonon mode. Although Damon and Klemens predicted and sought for such an effect, it has not previously been recornized.

We emphasize that errors in geometrical shape factors \$\(\lambda \) A for our specimes, and in the correction for bubbles do not significantly affect the temperature (T) variation of

a or Δ and in particular the qualitative features of the Δ -T curve which we associate with the local mode.

ACKNOWLEDGEMENTS

I thank Dr. S.B. Woods, first of all, for suggesting this project. As—a supervisor, he has given me the independence to work on my own, to make and learn from my own mistakes, yet he has always been available and helpful whenever I've asked and he has provided the necessary encouragement when I have needed it most. The knowledge and the values that I have learned from him go far beyond the discipline of physics alone. For all of this I am sincerely grateful.

For technical help, I am grateful to Mr. T. Valian and in the early stages of this work to Mr. H. McClung, to Ms. M. Johnson of Mineral Engineering for mounting and polishing several specimens and to Mr. D. Tomlinson of Geology for performing an electron probe microanalysis on these specimens.

I also thank Mrs. R. Nelson for typing this thesis so quickly, providing me with extra incentive to keep ahead during the final two weeks.

I would like to thank Dr. J.S. Rogers who was my acting supervisor in 1973-74 and Dr. A.B. Bhatia for numerous fruitful discussions. I am particularly grateful to Dr. J.A. Rowlands for his continued interest in my project and for many valuable suggestions.

Scholarships from the National Research Council and

the Izaak Walton Killam Memorial Trust as well as financial is support from the Physics Department are gratefully acknowledged.

Finally, I thank my wife Donna for her patience, assuming many of my family responsibilities over the past five years while I've been elsewhere.

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CHAPTER 1, INTRODUCTION

Seth and Woods (1370) measured deviations from Matthlessen's Pule (DMR or A) in a series of complementary dilute binary alloys (metal A in metal B and B 4; A) to test the theory of Enatia and Gupta (1969) about the effect of an interference term on IMR at high temperatures. For temperatures (T) above about 120 K, DMR were found to be linear in T, as expected, for all alloys except Cd-Mg, and, also as expected, negative for one allow of each complementary pair again except for the Cd-Mg pair. The high temperature slopes of the Δ versus T curves were negative for both Mg-Cd alloys (Hedgcock and Muir, 1964; Das and Gerritsen, 1964) and Cd-Mg alloys (Seth and Woods, 1970). In addition, the Δ -T curves for the $\underline{Cd}\text{-Mg}$ alloys were only linear from at it 80 K to 220 K where the slopes of these curves began to increase to more positive values. Seth and Woods suggest their apparently anomalous results could be due to different textures - grain structures and degrees of preferred crystallite orientation in different specimens. In a review on DMR, Bass (1972) suggests looking in anisotropic metals for anisotropy in Δ . Toussaint and Pecheur (1973) have in fact calculated curves for Δ -T in <u>Cd-Mg</u> and <u>Mg-Cd</u> for single crystal orientations both parallel and perpendicular to the c axis. Their calculations result in negative values of $d\Delta_{\gamma}/dT$ for both Cd-Mg and Mg-Cd at high temperatures, and furthermore, predict that Δ_3

the contribution to Δ due to the interference term, differs in the two symmetry directions by an order of magnitude. Measurements of DMR on single crystals would surely clarify the situation.

A second topic of recent interest is the temperature dependence of the anisotropy ratio, $\alpha = \rho_{\parallel}/\rho_{\perp}$. Case and Gueths (1970) measured the $^{oldsymbol{ au}}$ anisotropy ratio in tin and found a striking maximum of $a_{\text{max}} = a_{\infty}^{2}$ (where a_{∞} is the extrapolated value of a as $T + \infty$) at about 20 K. Completely. neglecting any effects due to anisotropy in the phonon spectrum, they explain their results in terms of a simplified model of the Fermi surface and predict the same temperature behaviour for any electrically anisotropic metal. In a review on galvanomagnetic effects in anisotropic metals, Hurd (1974) points to an urgent need for comparable data on other metals to test Case and Gueth's simple model. number of more thorough calculations, including one by White and Carbotte (1974) on Zn (which has a similar c/a ratio and Fer 1 s rface to Cd) have provided theoretical alternatives to Case and Geuths for comparison with experiment.

With both of the above problems in mind, we have prepared long, thin single crystals of varying crystal orientations, eight of high purity cadmium metal and twelve of dilute Cd-Mg alloys with three different concentrations. Electrical resistivities, the anisotropy ratio $a = \rho_{\parallel} / \rho_{\perp}$

and deviations from Matthiessen's Rule have been measured as functions of temperature from about 2 K to 330 K.

The next four chapters include respectively a brief outline of the theoretical background for these problems (Chapter 2), a description of our experimental procedure including specimen preparation (Chapter 3), the presentation of our experimental data and explanation of various corrections which have been made to the data (Chapter 4) and a discussion of our results (Chapter 5). The final chapter (Chapter 6) is a brief summary of our conclusions. At the end of the thesis are the bibliography and four appendices of which Appendix 1 on notation will be of most frequent use to the reader.

CHAPTER 2

THEORETICAL BACKGROUND

2.1 Ideal Resistivity and Anisotropy Ratio in Hexagonal Metals

An electric field, \vec{E} , produces an electric current density, \vec{J} , according to

where $\sigma_{\bf ij}$ is the electrical conductivity tensor. For metals with cubic crystal structures, \vec{J} is always parallel to \vec{E} and the tensor reduces to a constant. For metals with hexagonal crystal structures, the conductivity tensor has two independent components as shown:

$$\begin{pmatrix}
J_1 \\
J_2 \\
J_3
\end{pmatrix} = \begin{pmatrix}
\sigma_1 & 0 & 0 \\
0 & \sigma_1 & 0 \\
0 & 0 & \sigma_{||}
\end{pmatrix} \begin{pmatrix}
E_1 \\
E_2 \\
E_3
\end{pmatrix} (2.2)$$

 J_3 and E_3 are the components of \vec{J} and \vec{E} parallel to the caxis, the axis of six-fold or hexagonal symmetry. σ_1 and $\sigma_{||}$ are the electrical conductivities perpendicular to and parallel to the caxis. $\rho_1 = 1/\sigma_1$ and $\rho_{||} = 1/\sigma_{||}$ are the analogous components of the electrical resistivity tensor $\rho_{11} = (\sigma_{11})^{-1}$.

In long thin cylindrical single crystals of orientation θ (see Appendix 1 for notation), the resistivity $\rho(\theta)$ is the component of \vec{E} parallel to \vec{J} (which is parallel to the specimen axis) divided by $|\vec{J}|$ or:

$$\rho(\theta) = \vec{E} \cdot \vec{J} / |\vec{J}|^2 \tag{2.3}$$

It can easily be shown that:

$$\rho(\theta) = \rho_{\parallel} \cos^2 \theta + \rho_{\perp} \sin^2 \theta \qquad (2.4)$$

Note that resistivity is also a function of temperature and specimen composition, as well as orientation. For simplicity in notation throughout this thesis, the explicit dependence on one or more of these variables is often omitted.

Note secondly that there is also a component of \vec{E} perpendicular (or transverse) to \vec{J} for 0° < 0 < 90°. We show in Appendix 2 how both ρ_1 and $\rho_{||}$ can be obtained by measuring the parallel and the perpendicular components of \vec{E} in one single crystal.

In general, $\rho_{\parallel} \neq \rho_{\perp}$ and the anisotropy ratio is defined as $a = \rho_{\parallel}/\rho_{\perp}$, a function of both temperature and specimen composition.

Theoretical calculations of electrical resistivity generally start with the Boltzmann transport equation

(Ziman, 1969). $f = f_{\vec{k}}^+$ is the electron distribution function, the probability that an electron state with wave vector \vec{k} will be occupied. Under the influence of an electric field, the distribution function will change until a steady state is reached where

$$\left(\frac{\partial f}{\partial t}\right)_{\text{field}} + \left(\frac{\partial f}{\partial t}\right)_{\text{scatt.}} = 0$$
 (2.5)

 $\left(\frac{\partial f}{\partial t}\right)_{\text{field}}$ and $\left(\frac{\partial f}{\partial t}\right)_{\text{scatt}}$ are the rates at which the distribution function is changed by the electric field and by scattering processes respectively.

The electric current density, \vec{J} , is found by integrating the distribution function multiplied by the electron velocity, $\vec{v}_{\vec{k}}$, times the electron charge, e, over all possible \vec{k} states according to:

$$\vec{J} = 2 \int e \vec{v}_{\vec{k}} f_{\vec{k}} d^3 \vec{k}.$$
 (2.6)

Since $f_{\vec{k}}$ depends on \vec{E} , Eq. 2.6 is analogous to Eq. 2.1 and the conductivity tensor can be found by solving Eq. 2.5 and Eq. 2.6. In practice, this is difficult to do and simplifying assumptions are made.

Anisotropy in the electrical conductivity (and thus resistivity) arises because of:

- (1) anisotropy of the Fermi surface
- (2) anisotropy of the scattering process,

including anisotropy of the phonon spectrum (Pecheur and Toussaint, 1972). Since the scattering process is strongly dependent on temperature, the resistivity anisotropy $a = \rho_{\parallel \parallel}/\rho_{\perp}$, is also expected to be temperature dependent.

Case and Gueths (1970) proposed a simple theory for a_{m} based on an anisotropic Fermi surface beyond the first Brillouin zone but completely neglected the effects of anisotropy in the phonon spectrum. Their model predicts for any anisotropic metal, a maximum $a_{\text{max}} = a_{\infty}^{2}$ at low temperatures (\sim 20 K for Sn) falling off as $(a_m - a_{\infty}) \propto T^{-2}$ at high temperatures, a_{∞} being the anisotropy as $\mathbb{T} \to \infty$. They further predict that $a_{\infty} = \rho_{\parallel \parallel \infty}/\rho_{\perp \infty} = A_{\perp}/A_{\parallel \parallel}$ where $A_{\parallel\parallel}$ and A_{\parallel} are the areas of the Fermi surface extending beyond the Brillouin zone boundaries in the c ($|\cdot|$) and a (1) directions respectively. A final consequence of their theory is that a_0 , the unisotropy ratio as $T \rightarrow 0$, should return to the high temperature limit of a_{∞} . In spite of their oversimplified model, their own experimental results of the resistivity anisotropy for Sn show remarkable agreement with their predictions.

A number of other theorists, particularly Pecheur and Toussaint as well as Carbotte and co-workers have proposed more extensive calculations of electrical resistivities, initially for isotropic metals but more recently, these calculations have been extended to anisotropic materials as well. Most useful for comparison with the

experimental results presented in this thecia are the calculations by White and Carbotte (1974). They have found an approximate solution to the Boltzmann equation using a relaxation time approximation where the calculated relaxation times vary over the Fermi surface and take into account the phonon dispersion curves measured by inelastic neutron scattering. They plot curves of a versus temperature for pure Zn and also for dilute alloys of Zn, the latter both with and without the residual resistivities subtracted from the total resistivities. Qualitatively, the curve for pure Zn has all of the features predicted by Case and Gueths, except that a drops markedly below a_{-} at the lowest temperatures. Unfortunately, Cd strongly absorbs neutrons so that it is not possible to similarly obtain the phonon spectrum for Cd. However, the c/a ratios for Cd and Zn are similar as are their Fermi surfaces, so a comparison of our experimental results with their predictions is not unreasonable even without taking account of the different phonon spectra.

2.2 Deviations from Matthiessen's Rule

For a see binary alloy, the total resistivity $\rho_{\mbox{\scriptsize AT}}$ may be wreas

$$\rho_{AT} = \rho_{AC} + \Delta_{T}$$
 (2.7)

where $\rho_{\mbox{\scriptsize AO}}$ is the residual resist vity extrapolated as

T + 0, ρ_{1T} is the "ideal" resistivity for the pure host metal, and Δ_T is the "deviation from Matthiessen's rule" (DMR). For oriented single crystals of uniform impurity concentration; ρ_{AT} , ρ_{AO} and ρ_{1T} are all linear in $\cos^2\theta$ according to Eq. 2.4. Consequently, $\Delta_T(\theta)$ is also linear in $\cos^2\theta$ for a given concentration and can be written

$$\Delta_{\mathrm{T}}(\theta) = \rho_{\mathrm{AT}}(\theta) - \rho_{\mathrm{AO}}(\theta) - \rho_{\mathrm{1T}}(\theta)$$
 (2.8a)

$$\Delta_{\mathbf{T}}(\theta) = \Delta_{\mathbf{||T}} \cos^2 \theta + \Delta_{\mathbf{1T}} \sin^2 \theta \qquad (2.8b)$$

The explicit dependence of $\Delta_{\tilde{T}}(\theta)$ on concentration is omitted for simplicity.

Almost by definition, $\Delta_{\rm T}$ is small with respect to $\rho_{\rm AT}$. Since resistivities have not been calculated exactly, one would expect even less precision in theoretical calculations of DMR. Indeed, since about 1947, many theories for DMR have appeared, several of them still controversial. Bass (1972) has reviewed the subject and assessed the success of various theoretical models in the light of experimental work.

The features of DMR which have been reported in experiments on several metals include:

 $^{-}$ (1) a strong temperature dependence at lowest temperature, of the form \mathbf{T}^{n} where n varies from about 3 to 5.

- (2) a hump in many alloys at intermediate temperatures, often near the temperature where $\rho_{AO} \simeq \rho_{1T}$.
- (3) a linear region at relatively high temperatures (T > 150 K for many alloys) of the form Δ = mT + b where m and b are constants, b > 0 and m may be either positive or negative.

A fourth feature expected in some alloy systems due to a localized phonon mode (Damon and Klemens, 1965) is a change in slope to a more positive value at high temperatures (\sim 200 K for Cd-Mg). In previous experiments this feature had not been recognized.

A number of mechanisms have been proposed to give rise to DMR. Although Bass (1972) gives a more complete list, the most important ones are:

Matthiessen's rule to be valid, electrons are assumed to be scattered inelastically by phonons and elastically by static impurities, both processes operating independently. Because the impurities are not static, electrons can also be scattered inelastically by vibrating impurities.

Koshino (1960) calculated that a DMR proportional to T² at low temperatures would arise from one-phonon inelastic scattering by impurities. Taylor (1962, 1964) showed that two-phonon processes could not be neglected in the calculations and although he ultimately predicted a T² dependence as well, the term would be too small to measure. Klemens

(1963) produces a The like to the introduction of the case

on a time varying strain field around the impurities. The T^4 variation is in qualitative agreement with experiment (Damon, Mathur and Klemens, 1968) for $T\stackrel{<}{\sim} 20$ K.

- Two-band model Initially proposed by Sondheimer and Wilson (1947), the two-band model assumes that relaxation times are not isotropic on the Fermi surface (e.g. neck and belly regions in noble metals) and the anisotropies are different for two kinds of scattering mechanisms (i.e. impurities and phonons). Even though Matthiessen's rule is assumed to hold in each individual region, the two regions or bands, acting like resistors in parallel (i.e. their conductivities add), produce a DMR which is proportional to $\rho_{1\,T}$ at low temperatures (where $\rho_{1\,T}$ << $\rho_{A\,O})$ and proportional to ρ_{AO} at high temperatures. In a modification of the two-band model where the ratio of the ideal resistivities in the two bands is not constant, but a monotonic function of temperature, Dugdale and Basinski (1967) show that a hump which would be sharpest for the most dilute alloys could be produced at a temperature where $\rho_{1T} \sim \rho_{\Lambda O}$.
- (3) Interierence Term Kagan and Zhernov (1966) and Bhatia and Gupta (1969) calculated a contribution to the DMR from interference between scattering by impurities and scattering by phonons. Although values estimated by Kagan and Zhernov were too low to explain experimental

results, the term given by Bhatia and Gupta below was of the correct order of magnitude.

$$\Delta_3 = D 2c \int_0^1 W_A (W_B - W_A) S_{av}(x) x^3 dx$$
 (2.9)

where D = $12\pi m^2/\hbar^3 e^2 k_F^2$, $x = q/2k_F$, W_A and W_B are pseudopotential matrix elements for atom types A and B in a binary A-B alloy, and c (in this equation only*) is the fraction of B atoms. Δ_3 is significant at high temperatures where it is linear and may be either positive or negative (whereas all previous theories predicted strictly positive contributions to Δ in this temperature region). Furthermore, the sign of Δ_{3} would largely depend on the sign of $W_{\Delta}(W_{R}-W_{\Delta})$ in the neighbourhood of x = 1 and one would often expect the sign of Δ_2 to be opposite for complementary alloys (A-B and B-A). Toussaint and Pecheur (1973) have calculated values of Δ_3 for single crystals of $\underline{Cd}\text{-Mg}$ and $\underline{Mg}\text{-Cd}$ in parallel and perpendicular orientations. For both systems, they find negative values of Δ_{3} which are an order of magnitude larger for the parallel orientation than for the perpendicular orientation and they suggest experiments on single crystals as a possible check of the importance of the interference term. Unfortunately, it appears that in their calculations they have employed only the pure

^{*}Elsewhere in this thesis, x refers to atomic fraction of atoms (i.e. concentration) and c is the lattice parameter perpendicular to the hexagonal planes.

metal pseudopotential matrix elements, W_{Cd} and W_{Mg} , which may very well be significantly different from the pseudopotential matrix elements for the dilute alloys.

- Kagan and Zhernov (1971) were able to explain the observed variation of DMR over the entire temperature range in terms of anisotropy of the nonequilibrium electron distribution function. In the pure metal, this anisotropy arises primarily because of umklapp processes and may cause a decrease in the ideal resistivity of orders of magnitude. As impurities are added to the metal, elastic scattering by the impurities tends to suppress the anisotropy of the distribution function and the resistivity approaches the value expected for an isotropic distribution function.
- (5) Local modes When a dilute binary alloy consists of light impurity atoms in a lattice of heavier atoms, local modes of high frequency, ω_0 , appear in the phonon spectrum above the continuum (Damon and Klemens, 1965). Assuming that the interatomic force constants are the same for all atoms including the impurities,

$$\omega_{O} \simeq (M_{1}/M_{O})^{\frac{1}{2}} \omega_{D} \qquad (2.10)$$

where $\rm M_{1}$ and $\rm M_{0}$ are the masses of the host and impurity atoms respectively and $\omega_{\rm D}$ is the Debye frequency for the pure metal. Scattering by these localized phonon modes

would produce an increase in the electrical resistivity starting at about 10_0 where $0_0 = \hbar \omega_0/k_B$ is the characteristic emperature of the local mode (\hbar is Planck's constant divided by 2π and k_B is Boltzmann's constant). This appears as a contribution to DMR, Δ_μ , where

$$\Delta_{\mu}^{\alpha} = \Theta_{0}/(\exp(\Theta_{0}/T)-1). \qquad (2.11)$$

On a Δ -T graph, $\Delta_{\downarrow\downarrow}$ is expected to produce a change of slope to a more positive value at about T = $\frac{1}{2}$ O (\sim 200 K for Cd-Mg).

The interest in the experiments described in this thesis centers around the contributions to DMR, Δ_3 due to the interference term and Δ_4 due to local modes.

CHAPTER 3

EXPERIMENTAL DETAILS

Seth (1969) outlines the experimental procedures necessary for measuring deviations from Mattiessen's rule (DMR or $\Delta_{\rm T}$) and these procedures are more than adequate for measuring redistivity anisotropy. In order to calculate $\Delta_{\rm T}$ with reasonable accuracy, the geometrical shape factor f = t/A (where t is the length between potential contacts on a specimen of cross-sectional area t), the resistances t at all temperatures, and the residual resistances t extrapolated as t 0 K must all be measured extremely accurately. Specimens, up to ten at a time, must be held at the same constant temperature during ach measurement, whereas only modest accuracy is necessary in determining the temperature itself.

Aside from the specimen preparation, many of the experimental details are similar to Seth's work but with a number of improvements, most notably the specimen holder and the current comparator. Over the course of these experiments, further improvements suggested themselves but often too late to be incorporated. Some of these are summarized in Appendix 3 on suggestions for future resistivity measurements.

3.1 The Cryostat and Temperature Control

The cryostat and specimen holder used for the

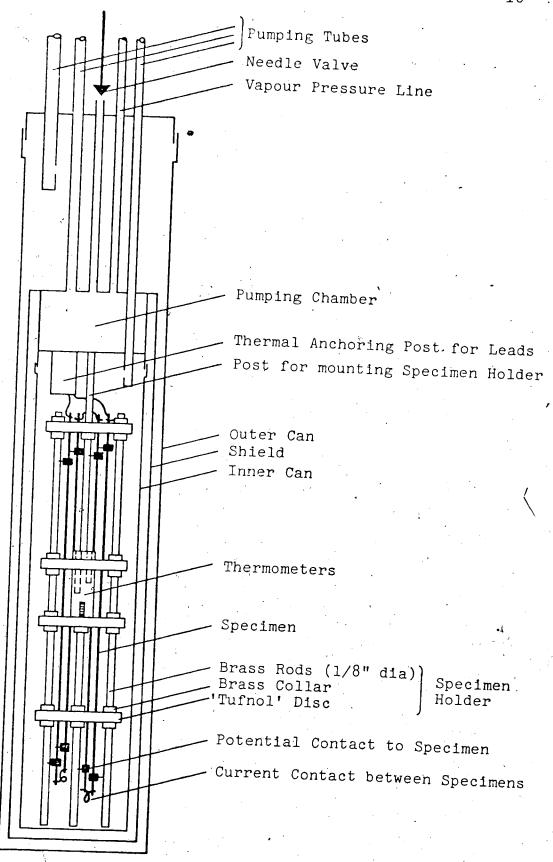


Fig. 1: Cryostat and Specimen Holder

resistance measurements are shown in Fig. 1. In order to free enough electrical leads to measure ten specimens simultaneously, the measuring current was brought into the cryostat through leads but returned through the stainless steel pumping tube. Aside from this modification, the cryostat is as Seth (1969) described.

The specimen holder consists of four 'Tufnol' discs, 2 in. in diameter and 1/4 in. thick, spaced 1-3 in. apart and held rigidly on three 1/8 in. diameter brass rods, 9 1/4 in. long by movable brass collars with et screws. The specimens, typically 8 in. long and 1 mm in diameter, slid freely through a series of aligned holes in the 'Tufnol' discs. The specimens were connected in series by soldering them at the ends to thin copper wires (AWG #28) and were supported in the specimen holder by the soldered current connection at the top end of each speci-Each wire was tinned with Sn-Pb solder (60% Sn) and had a double loop allowing both specimens and wires to expand and contract freely. Soldered current connections were used because local Joule heating at mechanical contacts can be significant, particularly at low temp ratures. The resistance between potential contacts on adjacent specimens was measured at 4.2K to check roughly that the solder joint resistances were low. Low resistance solder joints were most difficult to make on the alloy specimens of highest magnesium content. Care was taken during the

soldering process not to damage the single crystals beyond the immediate region of the solder joint.

To avoid constraining the specimens during thermal expansion or contraction, potential contacts were attached to the specimens only and not to the specimen holder. Thus, in addition to its own weight (~ 1.5 g), each specimen supported two potential contacts (~ 0.2 g each) consisting of a small 'Tufnol' cylinder 7 mm long and 5 mm in diameter with a hole slightly larger than the specimen diameter drilled perpendicular to the cylinder axis. small pointed brass screw parallel to the cylinder axis held the cylinder in place and made electrical contact with the specimen. The contacts should not be screwed any further than necessary into the specimen because the size of the indentation determines the uncertainty in length £, typically 1 part in 2000, a significant source of error in the ultimate values for resistivity. Finally, an electrical lead was soldered to the other end of the brass screw, the entire procedure executed with great care to avoid straining the single crystal specimens.

Resistances were measured at 4.2 K with a refrigerant bath of liquid He^4 at atmospheric pressure around the outer can. Temperatures below 4.2 K were obtained by pumping above liquid He^4 in the pumping chamber while maintaining a vacuum of better than 10^{-5} Torr in the outer can. A resistance bridge temperature controller was used

to obtain constant temperatures between 4.2 K and 63 K. To control the temperature, the amplified signal due to the difference between resistances of a carbon resistor mounted on top of the pumping chamber and a variable resistance set at a desired value, modulated the power fed to a 100Ω l watt heating resistor also mounted on top of the pumping chamber. Because the resistance of the carbon resistor was a strongly varying function of temperature, this controller provided a sensitive means of attaining stable temperatures, particularly below 77 K.

Liquid nitrogen was used as the refrigerant bath to obtain thermal equilibrium at 77 K and temperatures down to 63 K could be obtained by pumping above liquid nitrogen. From 77 K to about 260 K, stable temperatures were obtained using both the resistance bridge temperature controller and an additional 8 watt 12000 resistor fed by a variac. Additional measurements were made at room temperature, at 273.2 K using an ice water bath and, for the last run only, at 314 K and 327 K using warm water baths.

Thermal drift first became noticeable at about 15 K.

From that temperature upwards, the sequence of readings consisted of measuring temperature, measuring the specimen resistances, remeasuring the temperature, remeasuring the specimen resistances, and finally measuring the temperature a third time. This procedure took about thirty minutes (or longer at the lowest temperatures where

readings were taken to the limits of the voltage sensitivity) and during that time the drift in temperature was typically ±0.02 K above 77 K and ±0.003 K below 77 K.

The temperature drift was roughly linear in time so that by interpolating between the two sets of resistance measurements, it was possible to estimate the resistances at the time the second temperature was measured to about 2 parts in 10⁵ except where voltage sensitivity was the limiting factor. Although by waiting longer, one could have attained a more stable temperature before measuring the specimens, this was both impractical from the point of view of time and unnecessary for accuracy.

3.2 Temperature Measurement

A platinum resistance thermometer was used to measure temperatures above 77 K. This thermometer had been calibrated against another platinum resistance thermometer which the National Research Council of Canada had calibrated. The calibration points of resistance versus temperature were fitted to a Callendar-Van Dusen equation in order to determine intermediate temperatures. The resistance was measured by passing the same electric current of about $100\mu A$ through both the thermometer and a Leeds and Northrup 1000Ω standard resistor, and measuring the potential differences across each with a Fluke Model 8800A Digital Multimeter.

Below 77 K, temperature was measured with a germanium resistance thermometer which had been calibrated against an N.B.S. germanium thermometer from 2 K to 12 K and an N.R.C. platinum thermometer above 12 K. Temperatures for resistances between the calibration points were determined by graphical interpolation from 2 K to 12 K and by a computer least squares fit to an eleventh degree polynomial above 12 K. The resistance of the germanium thermometer was measured by a D.C. resistance comparator (Seth, 1969) using a Guildline 9801T precision four-terminal variable resistor for the comparison.

Both thermometers were inserted in wells in a copper cylinder, 1½ in. long and 1/2 in. in diameter, supported in the middle of the array of specimens by two of the 'Tufnol' discs in the specimen holder. The thermometers were coated with Wakefield thermal compound to improve the thermal contact with the copper cylinder.

Temperatures were determined to an accuracy of about ±0.025 K. Temperature stability however was an order of magnitude better i.e. the temperature at which the specimen resistances were measured was the same for all specimens to within a few millikelvin (mK).

3.3 Resistance Measurement

A Guildline Model 9920 Direct-Current Comparator
Bridge was used to compare the currents through an unknown

resistance (a specimen) and a four terminal standard resistor when the potential differences across each were balanced. The ratio of the unknown resistance to the standard resistance $R_{\rm S}$ could then be read directly to 1 part in 10^7 of $R_{\rm S}$ from seven dials on the comparator.

The difference in potentials could be zeroed with a sensitivity of about lnV using a Guildline Type 5214/9460 Photocell Galvanometer Amplifier and a Guildline Type 9461-A Galvanometer. A constant specimen current of \sim 100 mA meant specimen resistances could be determined to \sim 10⁻⁸ Ω .

Above 77 K, the standard resistor was a calibrated Guildline four-terminal 1Ω 0.1 watt standard resistor with a temperature coefficient of -1 ppm/°C. A four-terminal 0.01 Ω standard resistor was used below 77 K. This resistor was calibrated against the 1Ω standard resistor and found to be independent of current up to 1A to better than 1 part in 10^5 . For room temperatures between $22\frac{1}{2}$ °C and $28\frac{1}{2}$ °C, the 0.01 Ω resistor had constant resistance to better than 1 part in 10^4 . The two standard resistors were compared twice each run by measuring the specimens at 77 K against both.

Typical specimen resistances were 0.02Ω at 295 K and ranged at the lowest temperatures from 0.000002Ω for the pure specimens to 0.001Ω for some of the alloys. Nanovolt sensitivity was utilized at low temperatures for

all specimens while the comparator's seven figure accuracy was necessary only for the alloy specimens at low temperatures where $\rho_{AO} >> \rho_{iT}$ and $d\rho_{AT}/dT$ was small.

3.4 Specimen Preparation

The cadmium used in all specimens was obtained from Consolidated Mining and Smelting Co. of Canada and had 59 grade purity. The magnesium used in the dilute Cd-Mg alloy specimens was obtained from Johnson, Matthey and Co. and had impurities of less than 14 ppm.

3.4:1 Pure Cadmium Specimens

Long, thin cadmium single crystals of random orientations were grown using a Bridgman technique (Bridgman, 1925).

Cadmium ingots were placed in the funnel shaped top of a Pyrex mold after both the ingots and glassware had been rinsed with dilute hydrochloric acid, distilled water and isopropyl alcohol in succession and dried quickly by blowing helium gas over them. A loose fitting lid covered the mold to reduce evaporation losses of the cadmium. The mold itself was thin walled Pyrex tubing of approximately 1 mm inside diameter and about 25 cm long, closed to a point at the bottom.

Thin walled Pyrex tubing was readily available and could be dissolved relatively quickly (in about 2 hours)

using small quantities of hydrofluoric acid. The small variations in cross-sectional area, A, typically $\pm 1\%$ along a 20 cm specimen, do not produce a significant error in $f = \ell/A$ when an average value of A is determined by weighing a known specimen length and using known density values:

'A vertical furnace was lowered over part of a vacuum system in which the Pyrex mold was supported. I furnace consisted of a 20 in. length of 2 in. diameter stain as steel tubing around which were wrapped a layer of ambestos paper for electrical insulation, a 'Kanthal' ribbon heating element and several additional layers of asbestos paper for thermal insulation. The top of the furnace was filled with glass wool to reduce convective heat losses.

The resistance of the winding was about 40Ω and a 0-140V variac connected to the mains supplied the power. The furnace had been wound to obtain a steep thermal gradient at the bottom of the mold and a gradual thermal gradient towards the top. A variac setting of 120V brought the bottom of the mold to approximately the melting point of cadmium (321°C), the upper part of the mold being hotter.

A vacuum of about 10⁻⁴ Torr was maintained for several hours while the cadmium ingots in the funnel at the top of the mold were gradually heated to near the melting point. The variac was then turned up to 140V and the

ingots melted in about ten minutes. This was done quickly to minimize evaporation losses of the molten metal. Helium gas was admitted to the section of the vacuum system inside the furnace, forcing the molten cadmium down into the 1 mm diameter tubing. The variac was lowered to 120V and the system approached thermal equilibrium at that setting with a time constant of about 30 minutes. After about an hour, a small motor was turned on. It raised the furnace at a uniform rate of \sim 4 cm/hour until the furnace was completely above the specimen.

The Pyrex mold was dissolved in concentrated hydrofluoric acid and the specimen was rinsed with dilute hydrochloric acid, distilled water and isopropyl alcohol in succession and then dried. Each specimen was x-rayed at four points along its length both before and after being measured in a run. Orientations were determined to \sim ±1° by analyzing the Laue back reflection patterns. Nearly all of the specimens grown in this way turned out to be single crystals and with a few exceptions, the crystal orientations were constant within ±1° along each specimen's length. The good variety of specimen orientations obtained this way, including the most desirable orientations close to parallel and close to perpendicular, meant that growing specimens from seed crystals was not necessary.

Although the resistance ratios R_{295}/R_0 were typically

vidence of strain in the single crystals. Some of the Laue back reflection patterns were blurred, particularly when looking along crystal directions perpendicular to the c axis in which case the spots were often smeared out in the direction towards the c axis. Secondly, the residual resistances of Cd #24 and Cd #25, the two specimens used in all three reported runs, decreased by about 4-5% in the three month period during which these runs were made. These specimens had been grown about one month prior to the first of these runs and except during the runs themselves (of about a week to ten days each), the specimens were stored at room temperature.

Several possible specimens had been annealed for 12 hours at 125°C in an attempt to reduce strain. Indeed, the x-ray patterns did appear sharper after annealing and residual resistances were reduced. Unfortunately though, this procedure resulted in some recrystallization, observed both visually as well as with x-rays, and some of the best specimens were ruined. None of these annealed specimens are included in the experiments reported here.

With the exception of one specimen (which had been grown four years earlier and which is also not included in the results presented here), there was no visual or x-ray evidence that any of the specimens measured in the three runs had recrystalliz at all.

3.4.2 Cd-Mg Alloy Specimens

Three master alloys of cadmium with approximately 0.76, 1.5, and 5.6 atomic percent magnesium were made. For each master alloy, the cadmium and magnesium ingots were rinsed with dilute hydrochloric acid, distilled water, and isopropyl alcohol and then dried. The ingots were weighed and put into a Pyrex container consisting of thin walled tubing about 30 cm long and \sim 6 mm inside diameter with a bulb of \sim 4 cm diameter on one end. container was evacuated, then refilled with partial pressures of about 10 Torr of hydrogen gas (to prevent oxidation of the magnesium) and about half an atmosphere of helium gas, and then sealed. Using the same furnace described in Sec. 3.4.1 (as it could be easily removed from the motorized raising apparatus), the ingots in the bulb were heated to above the melting point of cadmium. The magnesium was initially observed floating in the molten cadmium. The whole furnace was shaken vigourously for 15 seconds every three minutes and after about twenty minutes no solid magnesium could be seen in the molten alloy. To ensure complete solution and thorough homogenization, the above shaking procedure was continued for a further twenty minutes. Then, the entire furnace was inverted, allowing the molten alloy to run quickly into the long, sealed tubing which protruded out of the furnace section. The alloy solidified within two minutes, forming crystallites with dimensions of ~ 1 mm or less.

After cooling, the Pyrex tubing was dissolved in hydrofluoric acid and the master alloy rinsed with dilute
hydrochloric acid, distilled water and isopropyl alcohol
and then dried.

To check that each master alloy was homogeneous, four potential contacts (similar to those described in Sec. 3.1 but proportionately larger) were attached along the length of the master alloy splitting it into three sections and the resistances of each section were measured at room temperature and at 4.2 K. For each master alloy, the values of $R_{295}/R_{4.2}$ were the same to within 0.5% for all three sections (except for one section of the Cdl.5Mg master alloy which was 4% lower than the other two sections and which was not used to make specimens), indicating uniform magnesium concentration along the length of each master alloy.

Side cutters were used to cut off sections 1 to 2 cm long from the master alloy. These sections were rinsed and dried and used to grow crystals in the same way described for the pure cadmium specimens (Sec. 3.4.1). The only difference was that the alloy specimens were raised to the melting point under a pressure of about 5 Torr of hydrogen gas, so prevent exidation of the magnesium, whereas the pure cadmium had been melted under vacuum.

3.4.3 Specimen Analysis

Because of possible preferred evaporation and/or ginhomogeneities in the specimens, the magnesium concentrations in the alloy specimens should be checked against some independent standard. The most reliable yardstick for this measurement was the set of residual resistivities for Seth's (1969) polycrystalline Cd-Mg specimens. These are summarized in Table 1.

According to Nordheim's rule (Meaden, 1965), the residual resistivity ρ_0 of a binary alloy is proportional to x(1-x) or $\sim x$ for a dilute alloy where x is the atomic fraction of the solute i.e. the concentration. Indeed, Seth's ρ_0 's for Cd-Mg do agree well with Nordheim's rule. Because ρ_{295} does not depend strongly on concentration, the resistivity ratio ρ_0/ρ_{295} is also nearly linear in x so that specimen concentrations can be determined by interpolating values of the resistance ratios $R_0/R_{295} \simeq \rho_0/\rho_{295}$ and are thus independent of the ℓ/A determination (which itself depends on the density of the alloy, the density in turn depending on the concentration).

For single crystals, the resistivities, ρ_0 and ρ_{295} , and thus the resistance ratios R_0/R_{295} also depend on orientation according to Eq. 2.4. Since the four single crystals grown from the Cd0.76Mg master alloy do show the expected variation with $\cos^2\theta$ (see Sec. 5.2 including Figs. 5 and 6), this series of alloys was used

Table 1

 ρ_0 , ρ_{295} , and ρ_0/ρ_{295} as functions of magnesium concentration in cadmium for polycrystalline wires (from Seth, 1969)

Mg conc. (at. %)	ρ _Ο (μΩ cm)	^ρ 295 (μΩ cm)	^ρ o ^{/ρ} 295
•		r	
0.0	0.0020	7.6090	0.00026
0.75	0.2217	7.7519	0.02861
1.5	0.4960	8.0462	0.06167
3.0	0.9920	8.4221	0.11738

to determine the orientation dependence of the resistance ratio.

To compa the resistivities of polycrystalline specimens and single crystals, Meaden (1965) uses

$$\rho_{\text{poly}} = (1/3)\rho_{\parallel} + (2/3)\rho_{\perp}$$
 (3.1)

The resistivity of a polycrystalline specimen $\rho_{\rm poly}$ is the same as that of a single crystal with an orientation such that $\cos^2\theta = 1/3$. We assume with this formula that there is no preferred orientation in the polycrystalline specimen. Although Seth's specimens do appear to have preferred orientations slightly closer to parallel than expected (see Sec. 5.2), this will not produce a significant error in the final results.

The magnesium concentrations determined by comparing the resistance ratios R_0/R_{295} to the ratios for Seth's specimens and allowing for the orientation dependence of the ratios are listed in Table 2. Also included in Table 2 are the specimen densities and the specimen bubble factors (see Sec. 3.5 and Sec. 4.1.3). The densities which are based on lattice parameters given by Pearson (1958) and which assume atomic masses of 112.41 and 24.305 for Cd and Mg respectively, depend on the Mg concentration. The calculated bubble factors depend in

Table 2

Magnesium concentration (atomic percent), densities (g/cm^3) and bubble factors at 295 K for \underline{Cd} -Mg alloy specimens.

Specimen	Mg Concentration	Density	Bubble Factor
Pure Cd	0.00	8.645	0.021-0.032
Cd0.76 Mg Master Alloy	0.90(±.04) [†]		∦
Cd0.76Mg #3	0.78(±. 9 4)	8.596(±.005)	0.028
Cd0.76Mg #5	0.78(±.04)	8.596(±.005)	0.030
Cd0.76Mg #6	0.78(±.04)	8.596(±.005)	0.022
Cd0.76Mg #8	0.78(±.04)	8.596(±.005)	0.029
Cdl.5Mg Master Alloy	1.73(±.08) [†]		
Cdl.5Mg #1	1.34(±.08)	8.560(±.008)	0.033
Cdl.5Mg #2	1.23(±.07)	8.567(±.007)	0.031
Cdl.5Mg #3	1.42(±.15)	8.555(±.012)	0.032
Cdl.5Mg #4	1.40(±.11)	8.556(±.009)	0.029
Cd5.6Mg Master Alloy	5.0(±.5) [†]		
Cd5.6Mg #2*	1.63(±.11)	8.542(±.009)	0.076
Cd5.6Mg #3*	1.66(±.11)	8.540(±.009)	0.089
Cd5.6Mg #4*	1.89(±.14)	8.525(±.011)	0 2069
Cd5.6Mg #5*	1.80(±.12)	8.531(±.010)	0.077

^{*}These calculations assume the alloys are homogeneous which is not the case for the Cd5.6Mg specimens.

 $^{^{\}dagger}$ Master alloy concentrations were determined using $^{\rm R}$ 4.2 $^{\rm R}$ 295 $^{\rm rather\ than\ R}$ o $^{\rm R}$ 295 $^{\rm rather\ than\ R}$

turn on the calculated densities.

For the Cd0.76Mg and Cd1.5Mg specimens, the calculated concentrations are reasonably close to the expected concentrations based on the weights of the Cd and Mg ingots before alloying (i.e. 0.76 at. % and 1.5 at. %). The calculated concentrations for the Cd5.6Mg specimens, however, are significantly lower than expected, even though the Cd5.6Mg master alloy had close to the expected concentration. The calculated bubble factors which depend on the density and concentration calculations are also anomalously large for the Cd5.6Mg alloys.

To look for small scale specimen homogeneity, an x-ray microanalysis with an electron probe was performed* on one specimen for each magnesium concentration. Whereas the Cd0.76Mg and Cdl.5Mg specimens did appear reasonably homogeneous on this scale, the Cd5.6Mg specimen was definitely not homogeneous. Although the results obtained using this technique cannot be used to determine accurate absolute Mg concentrations, they indicated that the Cd5.6Mg specimen did contain significantly more Mg than the other two specimens. These results suggest that during the growth of the single crystals much of the magnesium went into some more ordered state (a Cd3Mg

^{*}The author is grateful to Ms. M. Johnson of the Department of Mineral Engineering, University of Alberta for mounting these specimens for microanalysis and to Mr. D. Tomlinson of the Department of Geology, University of Alberta for performing these analyses.

superlattice is a possibility) than a random substitutional alloy (this type of explanation would also account largely for the high calculated bubble factors), but the phase diagram for Cd-Mg given by Hansen (1958) doesn't show any other phase close to that magnesium concentration. Because of the inhomogeneity in this specimen and the absence of a good explanation for it, the Cd5.6Mg specimens are omitted from the results presented in this thesis.

3.5 Experimental Procedure

The average cross-sectional area of each specimen was determined by weighing a known length of the specimen and using assumed densities based on lattice parameters (Pearson, 1958). Average cross-sectional areas were also calculated from diameter measurements using a micrometer caliper and found to be typically $2\frac{1}{2}$ % larger for both specimen diameters of \sim 1 mm and \sim 3 mm.

Assuming that the discrepancy in cross-sectional area is due to voids throughout the bulk of the specimen, a travelling potential probe (Seth, 1967) was used to scan the specimen for large voids which did not appear on the surface. By measuring the resistance of 10 cm lengths at ~ 1 cm intervals along the specimen, a large void would appear as an increase or decrease in the resistance as the probe moved along the specimen to include or exclude a void in the 10 cm length. Because

of the uncertainty in the length, this probe could only 'see' voids with dimensions of $\sim 1/2$ the specimen diameter ($\sim 1/4$ of the specimen cross section) or larger. No voids which were not already apparent visually on the surface were detected.

Specimens selected for measurement were mounted in the specimen holder with the potential contacts positioned on the specimens to exclude any large voids, and the inner can was soldered on. The inner can was then immersed in liquid nitrogen to ensure that a good vacuum could be obtained and then warmed to room temperature so the outer can could be soldered on. Although this procedure effectively constituted thermal cycling no systematic change in the resistance of the specimens was observed, probably because the specimens were able to expand and contract freely in the specimen holder.

After the run, the specimens were removed and the length, ℓ , between the indentations made by the potential contacts was measured by a cathetometer with the telescope replaced by a microscope. The specimen was cut with a razor blade as close to the indentation points as possible. This length, ℓ ' (\sim ℓ), was weighed and the average crosssectional area was remeasured as previously described. The geometrical shape factor, $f = \ell/A$ was calculated from these measurements.

CHAPTER 4

EXPERIMENTAL RESULTS

4.1 Analysis of Results

Electrical resistivities were calculated from the measured resistances and the measured geometrical shape factors at 293 K f_{293} = (ℓ/A)₂₉₃ according to

$$\rho_{\mathbf{T}} = R_{\mathbf{T}}(\mathbf{A}/\mathbf{l})_{\mathbf{T}} \tag{4.1}$$

where $(A/l)_T$ has been corrected for thermal expansion as described in Sec. 4.1.1. Although it would also be appropriate to correct experimental resistivities for changes in atomic volume (Sec. 4.1.2), this correction cannot be calculated with confidence and has therefore not been applied. In Sec. 4.1.3, a correction to Eq. 4.1 due to bubbles in the specimens is explained. Sources of error, primarily in the geometrical shape factor f = l/A are discussed in Sec. 4.1.4. Finally, in Sec. 4.1.5 the experimental results with calculated values of resistivities, the anisotropy ratio $\alpha = \rho_{||}/\rho_{||}$ and deviations from Matthiessen's rule Δ are presented in tables. Graphical presentation of the data is included in Chapter 5 where the results are discussed.

4.1.1 Corrections for Thermal Expansion

Thermal expansion affects the electrical resistivities of anisotropic single crystals in three ways:

- (1) because thermal expansion is anisotropic, the crystal experiences slight changes in orientation with changes in temperature.
- (2) the geometrical shape factor changes with temperature and because thermal expansion is anisotropic, the correction for this change depends on specimen orientation.
- (3) the atomic volume changes on thermal contraction, an effect discussed in Sec. 4.1.2.

McCammon and White (1965) gave a table of linear expansion coefficients for cadmiumwin directions both parallel to and perpendicular to the c axis from 293 K to 3 K. From their data, values of $(L_T/L_{293})_{\parallel}$ and $(L_T/L_{293})_{\perp}$ have been calculated and are tabulated in Table 3.

Because of anisotropic thermal contraction, the orientation θ_T at a temperature T differs slightly from the orientation θ_{293} measured at 293 K. In Appendix 4, it is shown that

$$\tan \theta_{T} = \frac{(L_{T}/L_{293})_{\perp}}{(L_{T}/L_{293})_{\parallel}} \tan \theta_{293}$$
 (4.2)

Table 3

 (L_T/L_{293}) , $(L_T/_{293})_{\perp}$ and correction factors for thermal contraction $(f_{||293}/f_{||T})$ and $f_{1293}/f_{1T})$ as functions of temperature (K) for pure cadmium.

Temp.	(L _T /L ₂₉₃)	(L _T /L ₂₉₃) ₁	(f ₂₉₃ /f _T)	(f_{1293}/f_{1T})
293	1.0000	1.0000	1.00000	1.00000
280	.99929	•99975	1.00021	.99929
260	.99819	•99937	1.00055	.99819
240	.99709	.99900	1.00091	.99709
220	.99598	.99865	1.00133	8
200	.99486	.99832	1.00179	• 1 <u>1</u>
180	.99374	.99801	1.00230	.99374
160	.99262	.99772	1.00285	.99262
140	.99149	.99745	1.00345	.99149
120	.99034	.99720	1.00411	.99034
100	.98918	.99698	1.00484	.98918
80 .	.98800	.99679	1.00566	.98800
60	.98680	.99665	1.00660	.98680
40.	.98565	.99660	1.00767	.98565
20	.98471	.99665	1.00873	.98471
0	.98451	.99668	1.00900	.98451

This change in orientation is largest for specimen orientations near 45° and at the lowest temperatures but even under these conditions, the change is negligible $(\theta_T - \theta_{293} \stackrel{?}{=} 0.35^\circ)$. Even so, this correction has been applied in plots of ρ versus $\cos^2\theta$ at low temperatures (Figs. 3 and 6 in Chapter 5).

The corrections to the geometrical shape factors f = l/A which will depend on both temperature and orientation can also be calculated using the data in Table 3. For example, the shape factor at temperature T for a specimen whose axis is parallel to the c axis $(\theta = 0^{\circ})$ would be:

$$f_{||T} = \left(\frac{\ell}{A}\right)_{||T} = \frac{\ell_{293} (L_T/L_{293})_{||T}}{A_{293} L_T/L_{293})_{||T}^2}$$

$$= f_{||293} \frac{(L_T/L_{293})_{||T}}{(L_T/L_{293})_{||T}^2}$$
(4.3a)

Similarly,

$$f_{\perp T} = f_{\perp 293} \frac{(L_T/L_{293})_{\perp}}{(L_T/L_{293})_{\parallel}(L_T/L_{293})_{\perp}}.$$
 (4.3b)

For off-axis orientations:

$$(L_{T}/L_{293})_{\theta} = (L_{T}/L_{293})_{\parallel} \cos^{2}\theta * (L_{T}/L_{293})_{\downarrow} \sin^{2}\theta.$$
 (4.4)

This result assumes that the orientation 9 is independent

of temperature. In fact, the orientation does change with temperature, but as previously mentioned the change is negligible. When the orientation change is included in Eq. 4.4, the final resistivities change by less than 1 part in 10⁴. Using Eq. 4.4, the shape factor at temperature T is:

$$f_{T}(\theta) = \left[\frac{(L_{T}/L_{293})|\cos^{2}\theta + (L_{T}/L_{293})|\sin^{2}\theta}{(L_{T}/L_{293})|\cos^{2}\theta + (L_{T}/L_{293})|\sin^{2}\theta} \right]$$

$$\times f_{293}(\theta). \tag{4.5}$$

Since resistivities are calculated by dividing by f_{293} , these resistivities have been multiplied by a correction factor $f_{293}(\theta)/f_T(\theta)$, a function of both orientation and temperature which can be found using Eq. 4.5. Values of the correction factor for specimens in the two extreme orientations ($\theta = 0^{\circ}$ and $\theta = 90^{\circ}$) are also included in Table 3. As one can see, the orientation dependence is significant.

Pearson (1958) gives lattice parameters above 293 K for Cd and Cd-Mg alloys from which thermal expansion coefficients can be calculated. By interpolating the thermal expansion coefficients to dilute alloys (the alloys Pearson quotes have 9.4, 22.0 and 24.8 at. % Mg), they appear to be within 5% of the values for pure Cd.

Thermal expansion data for <u>Cd-Mg</u> alloys are not available below 293 K and consequently, the same correction that is applicable to pure Cd also has been used for the alloys.

4.1.2 Corrections due to Changes in Atomic Volume

Theoretical resistivity calculations assume that the atomic volume is constant. Because the atomic volume changes on both thermal contraction and alloying, the electrical resistivities should be corrected for this change. Dugdale and Basinski (1967) calculated a correction which is based on the pressure derivatives of the resistivities.

The strains e_{xx} and e_{zz} in the a and c directions respectively under uniform hydrostatic pressure p can be calculated from the elastic compliance constants s_{ij} according to:

$$\begin{pmatrix}
e_{xx} \\
e_{yy} \\
e_{zz} \\
e_{yz} \\
e_{zx} \\
e_{xy}
\end{pmatrix} = \begin{pmatrix}
s_{11} & s_{12} & s_{13} & 0 & 0 & 0 \\
s_{12} & s_{11} & s_{13} & 0 & 0 & 0 \\
s_{13} & s_{13} & s_{33} & 0 & 0 & 0 \\
0 & 0 & 0 & s_{44} & 0 & 0 \\
0 & 0 & 0 & 0 & s_{44} & 0 \\
0 & 0 & 0 & 0 & 0 & 2(s_{11}-s_{12})
\end{pmatrix}
\begin{pmatrix}
p \\
p \\
p \\
0 \\
0 \\
0
\end{pmatrix}$$
(4.6)

Using Bridgman's values quoted by Alexandrov and Ryzhova (1961) for the compliance constants of Cd, we find the

strain in the c direction due to uniform pressure to be nine times the strain in the a direction at room temperature. Changes in length due to the thermal contraction are not nearly as anisotropic, the ratio in thermal expansion coefficients $\alpha_{\parallel \parallel}/\alpha_{\perp}$ being about three at room temperature. Because the nature of the volume changes due to uniform hydrostatic pressure and thermal contraction is different in anisotropic metals, any correction which assumes these processes to be equivalent is questionable. Furthermore, precise data on the temperature dependence of dp/dp is not available (Seth, 1969). For these reasons, the resistivities quoted here have not been corrected for changes in atomic volume due to thermal contraction.

For similar reasons, no correction has been applied for changes atomic volume on alloying. Such a correction would also be based on pressure-resistivity data and would depend on correlating two even more different effects - the addition of impurities on localized sites and the application of uniform pressure. Because adding Mg to Cd produces a decrease in c but an increase in a (c and a being the lattice parameters), the effect of pressure on atomic volume does not even agree qualitatively in this respect with alloying. In addition, one must also assume that the thermal expansion of the alloys and the pure metal are the same, until accurate expansion

data for the alloys becomes available below room temperature. Finally, there is no pressure-resistivity data available for \underline{Cd} -Mg alloys.

Dugdale and Basiński (1967) estimate their largest correction to be about 1/3 of the measured DMR at room temperature. Although we do agree that corrections would be appropriate if they could be calculated confidently, these calculations require too many assumptions and approximations to justify that confidence. Since Seth and Woods (1970) have also left out these corrections for many of the same reasons, our results on DMR in single crystals can be directly compared with theirs in polycrystalline specimens.

4.1.3 Corrections due to Bubbles

The cross-sectional areas of the specimens calculated from weighings were found to be systematically ~ 2½% lower than micrometer measured cross-sections. This discrepancy represents the 'bubble factor' B, the fraction of the specimen volume which consists of voids or bubbles, many of them visible on the surface. The bubble factors for each specimen have been included in Tables 2, 4a, 4b, 4c, 5a, and 5b.

To correct the resistivities for the effect of bubbles, we utilize an equation given by Landauer (1952) for the electrical conductivity of binary metallic mixtures:

$$\sigma_{m} = \frac{1}{4} \{ (3x_{2}-1)\sigma_{2} + (3x_{1}-1)\sigma_{1} + [((3x_{2}-1)\sigma_{2} + (3x_{1}-1)\sigma_{1})^{2} + 8\sigma_{1}\sigma_{2}]^{\frac{1}{2}} \}$$

$$(4.7)$$

where σ_1 , σ_2 and σ_m are the electrical conductivites of material 1, material 2 and the mixture, and x_1 and x_2 are the fractions of the total volume occupied by materials 1 and 2 respectively. To obtain this result, Landauer solved Maxwell's equations for spherical inclusions of one material embedded in the uniform mixture. If material 2 represents bubbles, then $\sigma_2 = 0$, $x_2 = B$, $x_1 = 1-B$ and Eq. 4.7 simplifies to:

$$\sigma_{\rm m} = (1 - 1.5B)\sigma_{\rm 1}$$
 (4.8)

Similarly, in terms of resistivities:

$$\rho_1 = (1 - 1.5B) \rho_m . \tag{4.9}$$

The calculated resistivities based on crosssectional areas found by weighing specimens is effectively

$$\rho_{lcalc} = (A_1/\ell)R$$

$$= ((1-B)A_{total}/\ell)R \qquad (4.10)$$

= $(1-B)\rho_{m}$

where A_1 is the average cross-sectional area of material 1 only found by weighing (thus excluding the cross-sectional area of the bubbles) and $A_{\rm total}$ is the total cross-sectional area measured with the micrometer caliper. Comparing Eqs. 4.9 and 4.10, we see that the calculated resistivities underestimate the effect of bubbles. Resistivities have therefore been multiplied by a correction factor (1-1.5B)/(1-B).

A crude way of interpreting this is to think of each bubble as having two 'shadows', small volumes of material one in front of and one behind the bubble which together have a volume of one half the bubble volume and which do not conduct electricity.—Although the weighing procedure eliminates the non-conducting bubbles from the calculation of effective cross-sectional area (Eq. 4.10), it does not eliminate the non-conducting shadows. I the bubbles had been either flattened or elongated the readtive volume of the shadows and therefore the necessary

Ear er experimenters have also had problems with

bubbles. Bridgman (1925) discusses the importance of getting rid of occluded gas before making single crystals. Unfortunately, molten cadmium evaporates quickly under a vacuum so that Bridgman's technique of washing the molten metal back and forth for up to an hour or more is impractical. This procedure would be particularly inconvenient for the alloys because of preferential evaporation of one of the two components. Edwards et al (1952) reported a discrepancy of ~ 2% between the measured density and the x-ray density for Cd-Mg alloys (but not for pure Cd), although Ridley (1964) obtained consistent densities for ingots whose preparation included swaging to ensure freedom from porosity.

4.1.4 Accuracy of Results

The major source of error was in determining accurately the geometrical shape factor $f = \ell/A$ for the specimens. Using the screw type potential contacts, the probable error in ℓ/A was about 2 parts in 10^3 . The pointed brass screws were set in far enough to make good electrical contact (in the case of one specimen, Cd0.76Mg #6, electrical contact was lost from about 8 K to 56 K but later regained), thus leaving a finite pit and corresponding uncertainty. In spite of prior thermal cycling, the resistivities and deviations from Matthiessen's rule occasionally showed small discrepancies when several

measurements were taken at approximately the same temperature, usually 77 K or room temperature. As the nature of these discrepancies were not systematic (Cd0.76Mg #5 and Cd0.76Mg #8 show opposite effects at 77 K), possibly the exact point on the specimen at which electrical contact was made varied over the course of a run. Another small error was introduced when the specimens were cut prior to weighing. In addition to the uncertainty in the length measurement, the specimens appeared to stretch slightly during the cutting procedure. The mass of a specimen was typically 1.5 g with an uncertainty of ± 0.5 mg. A final error, applicable only to the alloy specimens, is the uncertainty in density produced by the uncertainty in magnesium concentration. All of these errors are included in the uncertainties in $(l/A)_{295}$ which are quoted for each specimen in Tables 4a, 4b, 4c, 5a, and 5b.

An additional error arises when the correction due to bubbles is applied to the resistivities. Because of errors in the micrometer measurement of specimen diameter, the probable error in determining the bubble factor is ± 0.004 and the resulting probable error in the corrected resistivities $\pm 0.2\%$. Although this is effectively another error in ℓ/A , it has been indicated separately in the tables.

4.1.5 Presentation of Data

8

The data in Tables 4a, 4b, 4c, 5a, and 5b include the measured values of electrical resistance and the electrical resistivites, ρ_1 and ρ_A of pure and alloy specimens, as well as calculated values of ideal resistivity anisotropy $a_1 = \rho_{\parallel}/\rho_{11}$ and deviations from Matthiessen's rule Δ for each alloy specimen. Both ρ_1 and ρ_A have been calculated with the correction for thermal expansion of the geometrical shape factor (f = ℓ/A) included. Although the correction factor for bubbles (1-1.5B)/(1-B) is not included in the f = ℓ/A values quoted in the tables, it has been included in the calculations of the resistivities.

For the pure cadmium specimens, the residual resistivities have been subtracted in determining ρ_1 , whereas, the residual resistivities have not been subtracted in determining the alloy resistivities, ρ_A . $\rho_1||$ and ρ_{11} were determined at 273.15 K and 26.34 K (where the anisotropy ratio is near its maximum value) by fitting the ideal resistivities of all 8 pure Cd specimens to $\cos^2\theta$ (see Figs. 2 and 3 in Chapter 5). The lines which pass 1% below the point for Cd #24 (θ = 88 3/4°) and 1% below the point for Cd #25 (θ = 8°) in each graph represent best visual fits for these data. At other temperatures, $\rho_1||$ and ρ_{11} were calculated using the resistivities of Cd #24 and Cd #25 only and assuming the

same fit. The anisotropy ratio $a_i = \rho_{i||}/\rho_{ii}$ was then calculated.

A special procedure was used for Cd #24 because of a reasonably large bubble in the middle of it. Four potential contacts were attached along its length and the electrical resistance was determined between three different pairs of contacts at each temperature. The section which showed the least variation in resistance with thermal cycling (this type of small discrepancy has been discussed in Sec. 4.1.4) over the course of a run was used in the calculations of ρ_{1} and ρ_{1} .

Deviations from Matthiessen's rule were calculated for each allow specimen according to:

$$\Delta_{\mathbf{T}}(\theta) = \rho_{\mathbf{A}\mathbf{T}}(\theta) - \rho_{\mathbf{A}\mathbf{O}}(\theta) - \rho_{\mathbf{1}\mathbf{T}}(\theta)$$
 (2.8a)

where θ is the orientation of the alloy specimen and $\rho_{\mbox{iT}}(\theta) \mbox{ is determined from the calculated axial resistivities according to}$

$$\rho_{iT}(\theta) = \rho_{i||T} \cos^2 \theta + \rho_{iT} \sin^2 \theta \qquad (2.4)$$

Resistances are accurate to about 1 part in 10^4 at high temperatures and about $\pm .005 \mu\Omega$ at low temperatures. (Note that for the alloy specimens, this is considerably better than 1 in 10^4) whereas resistivities are only

accurate to ~ 2 in 10^3 because of uncertainties in ℓ/A . Subscripted numerals in the following tables are not significant in absolute magnitude. However, the fourth decimal place in Δ is significant in determining the temperature variation above about 65 K. Also, even though ρ_{AT} and ρ_{AO} are never themselves significant beyond the fourth decimal point due to the uncertainty in ℓ/A , their difference $\rho_{AT} - \rho_{AO}$ is significant to ~ 3 in 10^3 and is used to determine Δ . The extra figures are quoted in ρ_{AT} below about 19 K for this reason.

Table 4a

 $R(\mu\Omega)$, $\rho_1(\mu\Omega$ cm) and α_1 as functions of Temperature (K) for pure cadmium specimens used in Run #3.

Cd #24 (Bottom)
$$R_o = 1.410 \ (\pm .005) \mu\Omega$$

 $\theta = 88 \ 3/4^{\circ} \ (\pm 1 \frac{1}{4}^{\circ})$
 $(2/A)_{295} = 1388.1(\pm 3) \ cm^{-1}$
 $B = 0.023(\pm 0.004)$
Cd #25 $R_o = 4.241(\pm .005) \mu\Omega$
 $\theta = 8^{\circ} \ (\pm 3^{\circ})$
 $(2/A)_{295} = 3454.4(\pm 4) \ cm^{-1}$
 $B = 0.026(\pm 0.004)$

Cd	#24 (Bott	om)		Cd	#2 <u>5</u>	•
Temp.	R	ρ ₁	•	R	ρ _i	a_{1}
2.18	1.420	0.000007		4.253	0.000003	-
2.99	1.44 ₀	0.00002		4.290	0.000014	0.7
4.13	1.564	0.000108		4.59 ₀	0.00010	0.9
4.20	1.576	0.00011,		4.565	0.000093	ď.8
6.09	2.690	0.000897		7.200	0.000852	0.95
7.73	5.74 ₀	0.003034		15.760	0.003318	1.10
9.89	14.565	0.009219		43.57 ₀	0.01133	1.236
-13.16	42.830	0.02903		139.46	0.03894	1.352
18.86	136.46	0.09465	14	477.43	0.1363	1.452

Table 4a (cont'd)

Cd #	24 (Bottom	<u>)</u>	Cd #25		
Temp.	R	٩	R	ρ ₁	<i>a</i> ₁
26.34	322.87	0.2254	1145.13	0.3284	1.470
28.66	389.85	0.2724	1377.10	0.3952	1.464
36.92	651.36	0.4559	2242.06	0.6439	1.424
47.96	1031.5	0.7230	3431.25	0.9855	1.374
62.02	1533.8	1.0764	4948.3	1.421	1.330
76.85	2057.4	1.446	6512.3	1.869	1.302
76.87	2058.1	1.446	6516.3	1.870	1.302
76.88	2058.1	1.446	6516.7	1.870	1.303
76.94	2059.95	1.447	6522.6	1.872	1.302
77.15	2061.3	1.448	6524.4	1.872	1.302
77.16	2068.1	1.453	6544.7	1.878	1.302
93.67	2651.0	1.865	8285.3	2.377	1.283
124.90	3736.5	2.634	11543.3	3.308	1.264
150.54	4621.8	3.263	14222.3	4.073	1.256
177.69	5557.3	3.929	17067.4	4.884	1.251
197.36	6236.1 ₅	4.414	19141.5	5.476	1.248
222.27	7102.9	5.035	21792.3	6.231	1.245
251.51	8043.0	5.711	24666.2	7.049	1.242
273.20	8912.1 ₅	63 3 5	27313. ₅	7.803	1.239
293.88	9667.0	6.880	29612. ₄	8.457	1.237
294.71	9696.9	6.901	29710.8	8.485	1.237
294.81	9700.7	6.904	29722.3	8.488	1.237

	<u>Cd #</u>	123	Cd	#7	Cd #	12
Temp	R	ρ ₁	R	ρ	R	$ ho_{ exttt{i}}$
2.18	1.283	0.000006	- · · · - · ·	-	1.185	0.000003
2.99	1.323	0.00002	1.402	0.000024	1.23 ₅	0.00002
4.13	1.520	0.00011	1.592	0.000118	1.445	0.00010
4.20	1.540	0.000119	1.600	0.000122	1.46	0.000106
6.09	3.25 ₀	0.000869	3.11 ₅	0.000876	3.39 ₀	0.00083
7 • 7,3	8.100	0.002998	7.68	0.003146	9.240	0.003027
9.89	22.92	0.009503	22.165	0.01035	27.62 ₀	0.009928
13.16	71.970	0.03103	71.380	0.03482	89.910	0.03331
i8.86	238.63	0.1042	242.62	0.1200	305.79	0.1144

Tables 4a (cont'd)

	Cd #23	3	<u>ca #7</u>		<u>ca #12</u>	2_
				•	R	ρ
Temp.	R	ρi	R	ρ ₁		_
26.34	570.00	0.2497	582.03	0.2887	734.12	0.2752
28.66	688	3016	701.40	0.3481	885.10	0.3319
36.92	1141	06	1150.85	0.5714	1457.44	0.5467
47.96	1780	\$53	1779.6	0.8839	2262.7	0.8490
62.02	2636.	1.158	22590.6	1.287	3305.6	1.241
76.85	3517.7	1.546	3429.7 ₅	1.704	4385.5	1.646
76.87	3519.1	1.547	3431.6	1.705	4386.9	1.647
76.88	3519.2	1.547	3431.75	1.705	4387.1	1.647
76.94	3523.5	1.549	3435.2	1.706	4392.6	1.649
77.15	3525.0	1.549	3437.0	1.707,	4394.0	1.649
77.16	3536.4	1.554	3447.9	1.713	4408.9	1.655
93.67	4517.1	1.987	4382.0	2.177	5611.5	2.107
124.90	6344.65	2.793	6127.6	3.044	7857.6	2.951
150.54	7839.4	3.455	7559.6	3.755	9698.1	3.644
177.69	9421.4	4.156	9078.7	4.510	11649-4	4.379
197.36	10572.5	4.667	10186.5	5.061	13070-0	4.915
222.27	12043.9	5.321	11602.4	5.765	14883.0	5.59 9
251.51	13636.35	6.031	13135.2	6.528	16847.1	6.341
273.20	15102.65	6.685	14545.25	7.230	18656.25	7.025
293.88	16378.3	7.255	15771.6	7.841	20228.7	7.620
294.71	16431.5	7.279	15822. ₉	7.866	20294 • 6	7.645
294.81	16438.0	7.282	15829.2	7.870	20302.3	7.648
	A		J			

		Table 4a (cont'd)	
Cd	# 29	$R_0 = 1.674(\pm .005) \mu\Omega$	
		$\theta = 24\frac{1}{2}^{\circ} (\pm 1^{\circ})$	
,		$(2/A)_{295} = 1742.8(\pm 4)$	cm ⁻¹
,		$B = 0.025(\pm 0.004)$	
Cđ	#27	$R_o = 2.592(\pm .005) \mu\Omega$	J.
		θ = 34½° (±1°)	
		$(2/A)_{295} = 3456.0(\pm 5)$	cm^{-1}
	,	$B = 0.026(\pm 0.004)$	en in de la companya di seriesa d Reference di seriesa d
Cd	# 28	$R_0 = 3.607(\pm .005) \mu\Omega$	* 5 · · ·
		$\theta = 22 \frac{1}{2}^{\circ} (\pm 1 \frac{1}{2}^{\circ})$	•
		$(2/A)_{295} = 3565.1(\pm 4)$	cm ⁻¹
		$B = 0.028(\pm 0.004)$	

		$B = 0.028(\pm 0.004)$	
	<u>Cd #29</u>	<u>Cd #27</u>	<u>Cd #28</u>
Temp.	R ρ_{1}	R ρ ₁	R P _i
2.18	1.682 0.000005	2.608 0.000005	3.62 ₅ 0.00000 ₅
2.99	1.70, 0.000019	2.66 ₀ 0.00001 ₉	3.67 ₀ 0.00001 ₇
4.13	1.864 0.000108	2.97 ₀ 0.00010 ₈	3.98 ₂ 0.00010 ₄
4.20	1.86 ₀ 0.00010 ₆	2.970 0.000108	3.97 ₀ 0.00010 ₁
6.09	3.240 0.000891	5.58 ₀ 0.00085 ₄	6.78 ₀ 0.00088 ₂
7.73	7.51 ₀ 0.00332 ₁	13.61 ₀ 0.00314 ₉	15.56 ₀ 0.00332 ₂
9.89	21.09 ₅ 0.01105	39.30 ₀ 0.01049	43.71 ₅ 0.01115
13.16	67.330 0.03736	126.68 0.03546	139.71 0.03783
18.86	229.06 0.1294	431.48 ^O 0.1226	476.27 0.1314
artining in the second of the			

Table 4a (cont'd)

	ca #	29	Cd #2	7	Cd #2	<u>8</u> .
Temp.	R		R	- ρ _i	R	ρ _i
26.34	548.91	0.3113	1035.06	0.2950	1141.2	0.3161
28.66	660.60	0.3748	1245.7	0.3552	1373.0	0.3804
36.92	1078.69	0.6125	2042.62	0.5828	2239.24	0.6209
47.96	1657.7	0.9414	3151.0	0.8992	3435.8	0.9528
62.02	2400.2	1.363	4580.6	1.307	4977.8	1.380
76.85	3165.8	1.797 -	6057.1	1.729	6546.85	1.815
76.87	3167.75	· · ·	6062.3	1.730	6550.4	1.816
76.88	3167.8 ₅	1.798	6062.6	1.730	6550.8	1.816
76.94	3170.85	1.800	6066.4	1.731	6557.6	1.818
77.15	3171.8	1.801	6067.4	1.731	6559.7	1.818
77.16	3181.8	1.806	6086.6	1.737	6580.4	1.824
93.67	4034.6	2.290	7738.4	2.207	8339.2	2.311
124.90	5629.5 ₅	3.193	10804.4	3.083	11628.7	3.220
150.54	6939.3	3.935	13323.6	3).801	14331.0	3.9 67
177.69	8330.0	4.722	16004.0	يل. 566	17199.9	4.759
197.36	9343.4	5.295	17949.2/	5.121	19290.7	5.3 3 7
222.27	10637. ₉	6.027	20439.0	5.832	21963.	6.074
251.51	12040.4	6.821	23138.7	6.603	24859.2	6.873
273.20	•	7.554	25626.7	7.314	27527.9	7.619
	14459-6		27786.2	7.932	29845.7	8.250
294.71		8.217	27875.8	7.958	29944 - 4	8.277
294.81	14514.0	8.220	27886.4	7.961	29956.0	8.280

Table 4a (cont'd)

Cd #24 (Top)
$$R_{o} = 1.180(\pm .005)\mu\Omega$$

$$\theta = 88 3/4^{\circ} (\pm 1\frac{1}{4}^{\circ})$$

$$(\ell/A)_{295} = 1388.1(\pm 2) \text{ cm}^{-1}$$

$$B = 0.024(\pm 0.094)$$

Cd #24
$$R_{o} = 2.678(\pm .005)$$

$$\theta = 88 3/4° (\pm 1½°)$$

$$(2/A)_{295} = 2863.7(\pm 5) cm^{-1}$$

$$B = 0.025(\pm 0.004)$$

	Cd #24 (Top)	ca #24
Temp.	R ρ_{1}	R ρ_{1}
2.18	1.19 ₀ 0.00000 ₇	2.69 ₀ 0.00000 ₄
2.99	1.21 ₀ 0.00002 ₁	2.740 0.000021
4.13	1.36 ₀ 0.00012 ₆	3.041 0.000123
4.20	1.350 0.000119	3.050 0.000126
6.09	2.478 0.000910	5.36 ₅ 0.00091 ₂
7.73	5.51 ₀ 0.00303 ₄	11.61 ₀ 0.00303 ₂
9.89	14.32 ₅ 0.00921 ₂	29.86 _{0 \$ 0.009226}
13.16	42.57 ₅ 0.02901	88.14 ₅ 0.02901
18.86	136.27 0.09468	281.52 0.09465
26.34	322.85 0.2255	666.56 0.2254
28.66	390.20 0.2728	805.30 0.2726
36.92	651.68 0.4563	1345.0 🐧 💈 0.4560

Table 4a (cont'd)

	ca #24 (Top)	ca #24	
Temp.	R	ρ ₁	R	ρ _i
47.96	1031.6	0.7232	2129.5	0.7230
62.02	r534.4	1.077	3166.7	1.076
76.85	2057.3	1.446	4247.3	.i.445
76.87	2060.6	1.448	4251.6	1.447
76.88	2059.7	1.447	4250.7	1.447
76.94	[©] 2060.7	1.448	4253.9	1.448
77.15	2065.1	1.451	4259.4	1.450
77.16	2071.8	1.456	4273.4	1.454
93.67	2654.1	1.867	5476.4	1.866
124.90	3741.0	2.637	7718.6	2.635
150.54	4625.5	3.265	9545.3	3.264
177.69	,5565.1	3.935	11481.	3.932
197.36	6247.6	4.422	12886.35	4.418
222.27	7115.6	5.044	14677.2	5.039
251.51	8057.8 ₅	5.721	16620.	5.715
273.20	8914.0	6.337	18401.4	6.336
293.88	9667.5	6.880	19957.8	6.879°
294.71	9699.8	6.904	20021.4	6.902
294.81	9703.6	6.906	20029 . 2 🖔	6.904

Table 4b

 $R(\mu\Omega)$, $\rho_{1}(\mu\Omega$ cm) and a_{1} as a function of Temperature (K) for pure cadmium specimens used in Run #4

Cd #24 (Top)
$$R_{o} = 1.148(\pm .005)\mu\Omega$$

 $\theta = 88 \ 3/4^{\circ} \ (\pm 1\frac{1}{4}^{\circ})$
 $(\ell/A)_{295} = 1388.9(\pm 2) \ cm^{-1}$
 $B = 0.024(\pm 0.004)$
 $R_{o} = 4.165(\pm .005)\mu\Omega$
 $\theta = 8^{\circ} \ (\pm 3^{\circ})$
 $(\ell/A)_{295} = 3455.3(\pm 4) \ cm^{-1}$
 $(\ell/A)_{295} = 3455.3(\pm 4) \ cm^{-1}$

	Cd #24	(Top)		cd #2	5		1920
Temp.	R	ρ ₁	. J	3	ρ _i	"	$a_{\mathbf{i}}$
1.72	1.150	1.00000	4.	.170	0.00000	L ,	- .
1.90	1.172	0.000017	<u> </u>	174	0.00000	3	- ,
2.21	1.177	0.00002	4.	181	0.00000	5	
3.15	1.208	0.000042	4.	237	0.00002	L	0.5
4.18	1.325	0.000124	ž.4.	480	0.00009	L .	0.7
4.25	1.350	0.000142	4.	.52 ₀	0.000102	2	0.72
4.95	1.590	0.000310	5.	.025	0.000248	3	0.80
6.04	2.420	0.000891	, · 7.	00.6	01000818	3	0.919
7.18	4.170	0.002117	11.	808	0.00220	L	1.043
8.00	6.200	0.003538	17.	800	0.00392	5	1.11 ₅

Table 4b (cont'd)

	Cd #2	Cd #24 (Top)		Cd #25		
Temp.	R	ρį	R	ρ_{1}	a _i	
9.92	14.46	00∑32	43.93	0.01145	1.236	
13.17	42.61	^ , or oc4	139.35	0.03892	1.950	
16.16	85.34	0.0589 7	291.36	0.08269	A STATE OF THE PARTY	
19.35	146,76	0.1020	514.59	0.1470	1.453	
23.09	235.47	0.1642	835.04	0.2392	1.470	
27.42	354.20	0.2474	1251.94	0,3591	1.464	
32.36	504.37	0.3527	1759.43	0.5050	1.444	
38.09	691.10	0.4837	2366.86	0.6796	1.417	
45.21	936.50	0.6560	3133.43	0.8998	1.382	
56.01	13 19.1 ₃	0.9250	4299.6	1.234	1.345	
64.55	1619.4	1.136	5208.0	1.495	1,325	
76.92	2059.25	1.446	6519.95	1.871	1.303	
76.94	2060.0	1.447	6525.2	1.872	1.303	
77.24	2080.0	1.461	6558.0	1.882	1.297	
₁ 00.11	2875.5 ₅	2.023	8960.9	2.569	1.279	
125.31	3748.7 ₅	2.641	11587.7	3.320	1.265	
148.74	4557.1	3.215	14034.1	4.018	1.258	
173.33	5411.5	3.823	16630.25	4.758	1.253	
201.97	6327.3	4.477	19416.25	5.552	1.248	
223.95	7166.75	5.078	21971.0	6.280	1.245	
250.70	8023.85	5.694	24575.3	7.021	1.241	
273.21	8917.35	6.336	27312.3	7.800	1.239	
293.43	9653.7	6.866	29558.9	8.439	1.237	
297.51	9805.4	6.976	30015.8	8.569	1.236	

Table 4c

 $R(\mu\Omega)$, $\rho_1(\mu\Omega$ cm) and a_1 as functions of Temperature (K) for pure cadmium specimens used in Run #5

Cd #24 (Bottom)
$$R_o = 1.360 (\pm .005) \mu\Omega$$

 $\theta = 88 3/4^{\circ} (\pm 1\frac{1}{4}^{\circ})$
 $(2/A)_{295} = 1391.3(\pm 3) \text{ cm}^{-1}$
 $B = 0.023(\pm 0.004)$
Cd #25 $R_o = 4.060(\pm .005) \mu\Omega$
 $\theta = 8^{\circ} (\pm 3^{\circ})$
 $(2/A)_{295} = 3455.5(\pm 4) \text{ cm}^{-1}$
 $B = 0.026(\pm 0.004)$

•	<u>cd #24</u>	(Bottom)	<u>Cd #25</u>		(B)
Temp.	R	, ρ,	R	ρ ₁	a _i
2.07	1.37	0.000007	4.07	0.000003	· -
3.04	1.40	0.000028	4.13 ₅	0.000022	0.8
4.18	1.53	0.000119	4.38 ₅	0.000094	0.8
4.97	1.78.	0.000294	4.95	0.000256	0.87
6.11	2.68	5.00092 ₃	7.09	0.000872	0.95
7.27	4.57	0.002244	12.30	0.002373	1.06
8.11	6.72	0.003748	18.67	0.004208	1.13
10.21	16.50	0.01059	49.74	0.01315	1.250
13.48	46.62	0.03165	152.37	0.4270	1.360
16.43	90.34	0.06222	308.44	0.08763	1.420
22.78	227.86	0.1584	806.96	0.2311	1.472

Table 4c (cont'd)

•	Cd #24	(Bottom)	<u>Cd #25</u>	•	
Temp.	R	ρ	R	ρ _i	a _i
26.60	331.25	0.2308	1171.98	0.3361	1.469
31.47	477.03	0.3328	1668.06	0.4788	1.451
36.72	646.21	0.4513	2221.5	0.6378	1.425
43.08	862.39	0.6028	2904.23	0.8340	1.395
48.20	1042.1	0.72	3457.67	0.9928	1.373
55.80	1312.6	0.9187	4277.28	1.228	1.347
65.35	1651.6	1.157	5294.4	1.520	1.323
7.6.95	2064.85	1.448	6522.6 ₅	1.871	1.302
103.61	3004.1.	2.110	9325.1	2.673	1.276
121.71	3632.2 ₅	2.554	11211.05	3.212	1.266
136.01	4127.8	2.905	12705.0	3.639	1.261
150.75	4636.4	3.266	14243.3	4.078	1.257
168.07	5233.7	3.690	16055.1	4.594	1.253
184.31	5796.4	4.091	17765.7	5.082	1.250
205.55	6533.35	4.616	20012.0	5.722	1.247
221.64	7093.8	5.017	21722.7	6.209	1.245
238.12	7673.6	5.432	23491.0	6.712	1.244
255.70	8298.2	5.880	25399.5	7.256	242
273.18	8930.5 °	6.334	27316. ₅	7.801	1.239
297.50	. 9817.7	6.973	30013. ₇	8.568	1.237
298.35	9846.5	6.993	30111.4	8.596	1.237
314.36					
326.95	10924.	7.772	33378. ₁₁		1.233

Table 5a

 $R(\mu\Omega)$, $\rho_A(\mu\Omega$ cm) and $\Delta(\mu\Omega$ cm) as functions of Temperature (K) for specimens made from Cd0.76Mg master alloy.

Cd0.76Mg #3	$R_{o} = 361.355(\pm .005) \mu \Omega$
	$\theta = 89\frac{1}{2}$ ° (±1°)
	$(\ell/A)_{295} = 1399.6(\pm 3) \text{ cm}^{-1}$
	$B = 0.028(\pm 0.004)$
Cd0.76Mg #5	$R_{o} = 715.590(\pm .010) \mu\Omega$
	$\theta = 83 \% \text{ ($\pm 1^{\circ}$)}$
	$(l/A)_{295} = 2754.3(\pm 4) \text{ cm}^{-1}$
	$B = 0.030(\pm 0.004)$

	CdO.	76Mg #3		CdO	.76Mg #5	
Temp.	R	$^{p}{}_{\mathbf{A}}$	Δ	R	$^{ m ho}{}_{ m A}$	Δ
1.72	361.36	0.2505	0.000007			
2.21	361.39 ₅	0.250549	0.000013	-	_ `.'	_
3.15	361.47 ₉	0.2506	0.000052	715.792	0.251989	0.00003
4.18	361.70 ₀	0.250766	0.000126	716.230		0.000112
4.25	361.76 ₄	0.2508 ₁₀	0.000153	716.344		0.000135
4.95	362.143	0.251075	0.00025	717.10		0.000237
6.04	363.33 ₅	0.2519 ₀₄	0.000502	720.08	-	0.00071
7.18	366.81	0.2543 ₁₆	0.001694	726.37		0.001705
8.00		•		733.49		0.002795
9.92	384.05	0.26628	0.00648	760.56	0.2677	-

Table	5a	(cont'd)
	_	\ · · · · · · /

				-	·)	
	_ <u>Cc</u>	10.76Mg #	3	CdO	.76Mg #5		
Temp.	R	$\rho_{\mathbf{A}}$	Δ	R	$^{ m ho}{}_{ m A}$. Δ	
13.17	423.6	0.2937	0.0142	9 839.18	0.2954	6 0.01451	
16.16	475.3	8 0.3296	0.02042	942.31	0.3317	0.020,85	
19.35	543.4	4 0.3768	0.0248	1077.86	0.3795	0.0255	
23.09	636.4	2 0.4414	0.0275	1262.86	0.4447	0.0284	
27.42	757.1	1 0.5252	0.0285	1502.72	0.5293	0.0297	
32.36	907.7	9 0.6298	0.0284	1801.7	0.6348	0.0298	
38.09	1094.5	0.7596	0.0278°	2171.97	0.7654	0.0294	
, 45.21	1338.3	0.9292	0.0259	2655.1	0.9360	0.0279	
56.01	1720.6	1.195	0.0245	3411.87	1.2035	0.0269	
64.55	2022.6	1.406.	0.0247	4009.9	1.415	0.0276	
76.92	2463.1 ₁	1.713	0.0238	4881.69	1.724	0.0273	
76.94	2464.0	1.714	0.0239	4883.7	1.725	0.027 ₄	
77.24	2485.0	1.729	0.0246	4903.0	1.732	0.0203	
100.11	3281.6	2.286	0.0228	6502.05	2.300	о.027 _и	
125.31	4157.5	2.900	0.022	8236.3 ₅	2.917	0.0278	
148.74	4968.6	3.471	0.0214	9842.2	3.490	0.0283	,
173.33	5826.0	4.075	0.0208	11539.85	4.098	0.028	
201.97	6744.3 ₅				4.751	0.029	
223.95	7587.1			15026. ₃		0.0297	•
250.70	8447.5		•	16727.8		0.0298	
273.21	9350.8	•		18521.		0.036 ₇	
293.43	10095.3			19994. ₄		0.0408	
297.51	10245.05		0.024 ₅ ;	•		0.041 ₉	
	• •			. 0		-9	•

Table 5a (cont'd)

Cd0.76Mg #6 $R_{o} = 503.035(\pm.005)\mu\Omega$ $\theta = 29^{\circ} (\pm 1^{\circ})$ $(\ell/A)_{295} = 2269.5(\pm 4) \text{ cm}^{-1}$ $B = 0.022(\pm 0.004)$ Cd0.76Mg #8 $R_{o} = 425.695(\pm.005)\mu\Omega$ $\theta = 16\frac{1}{2}^{\circ} (\pm 1\frac{1}{2}^{\circ})$ $(\ell/A)_{295} = 1976.8(\pm 4) \text{ cm}^{-1}$ $B = 0.029(\pm 0.004)$

Cd0.76Mg. #6

Cd0.76Mg #8

						•	
	Temp	R	$\rho_{\mathbf{A}}$	Δ	R	$^{ m ho}{}_{ m A}$	Δ
	1.72	· 		-	425.70 ₀	0.2136	
	1.90	503.075	0.219873	0.000009	425.726	0.213623	0.000008
	2.21	503.088	0.219878	0.000013	425.738	0.213629	0.000012
	3.15	503.21	0.219931	0.000048	425.847	0.213682	0.000049
	4.18	503.61 ₀	0.2201 ₀₄	0.000149	426.200	0.2138 ₅₈	0.000154
	4.25	503. 7 3 ₅	0.2201 ₅₉	0.00019	426.316	0.2139 ₁₆	0.00020
	4.95	505.000	0.2207	0.000593	427.036	0.214275	0.000413
	6.04	507.56 ₀	0.2218 ₂₅	0.001136,	429.880	0.215697	0.001265
	7.18	514.150	0.2247 ₀₄	0.00267	435.95 ₀	0.218740	0.002939
	8.00	521.50	0.2279 ₁₅	0.004228	442.81	0.222181	0.004677
	9.92	-	-	-	468.84	0.23524	0.01034
1	3.17	-		_	544.77	0.27332	0.02150

Table 5a (cont'd)

٠	• .	<u>cao.</u>	76Mg #6	.*	Cd	0.76Mg #8	
	Temp.	R.	$^{ m ho}{}_{ m A}$	Δ	R	^Р А	Δ
	16.16			-	645.50	0.3238	0.02924
	19.35	- j:	-	• •	778.48	0.3906	0.0332
	23.09	_	· •		958.49	0.4808	0.0333
	27.42	-		- -	1,187.0	0.5953	0.0305
	32.36	~	•••		1463.63	0.7339	0.0260
	38.09	-	-	· —	1795.53	0.9001	0.0208
	45.21	~	· -	-	2216.45	1.1107	0.0149
	56.01	_	•••		2860.2	1.4326	0.0071
	64.55	3719.3	1.623	-0.008 ₄	3363.4	1.684	0.0019
	76.92	4525.8	1.975	-0.0172	4092.5	2.048	-0.0048
	76.94	4528.3	1.976	0.0174	4095.3	2.050	-0.0048
	77.24	4553.0	1.987	-0.0170	4129.0	2.066	0.0023
	100.11	6028.5	2.629	-0.0322	5451.8	2.726	-0.0156
	125.31	9645.9 ₅	3.334	-0.0472	6916.2 ₅	3.456	-0.026 ₂
	148.74	9151.5	3.989	-0.0608	8280.0	4.135	-0.0358
	173.33	10749.35	4.685	-0.0744	9728.05	4.856	-0.0453
	201.97	12464.5	5.431	-0.0886	11283.65	5.629	-0.0547
	223.95	14041.05	6.118	-0.099 ₉	12713.8	6.341	-0.0614
	250.70	15649,65	6.818	-0.1108	14175.6	7.067	-0.0662
	273.21	17340.3	7 - 555	-0.121	15707.2	7.829	-0.0733
	293.43	18730.4	8.160	-0.128 ₉	16968.8	8.456	-0.0771
	297:51	19014.3	8.284	-0.1303	17224.6	8.583	-0.0783

Table 5b

 $R(\mu\Omega)$, $\rho_{\mbox{$A$}}(\mu\Omega$ cm) and $\Delta(\mu\Omega$ cm) as functions of Temperature (K) for specimens made from Cdl.5Mg master alloy.

Cd1.5Mg #3
$$R_{o} = 1462.055(\pm .005)\mu\Omega$$

$$\theta = 29\frac{1}{2}^{\circ} (\pm 1\frac{1}{2}^{\circ})$$

$$(\ell/A)_{295} = 3441.3(\pm 9) \text{ cm}^{-1}$$

$$B = 0.032(\pm 0.004)$$

$$R_{o} = 1219.120(\pm .005)\mu\Omega$$

$$\theta = 54^{\circ}(\pm 1^{\circ})$$

$$(\ell/A)_{295} = 2739.1(\pm 7) \text{ cm}^{-1}$$

$$B = 0.029(\pm 0.004)$$

	Cdl	.5Mg #3		. <u>Cd</u>	1.5Mg #4	:
Temp.	R	$\rho_{\mathbf{A}}$	Δ	R	$\rho_{\mathbf{A}}$	Δ
2.07	1462.08	0.419096	_	1219.14	0.435336	0.000004
3.04	1462.24	0.4191	0.000024	1219.3	0.435400	0.000048
4.18	1463.09	0.419381	0.000189	1220.0	0.435649	0.000214
4.97	1464.82	0.419873	.00051 ₅	1221.38	0.4361 ₄₁	0.000536
6.11	1470.58	0.421517	0.001543	1225.79	0.4377	0.001486
7.27	1482.92	0.4250 ₅₂	0.003623	1235.16	0.441060	0.003454
8.11	1496.62	0.428977	0,005792	1245:47	0.444743	0.005523
10.21	1553.65	0.4453	0.01369	1288.02	0.45994	0.01317
13.48	1701.47	0.48767	0.02851	1396.75	0.49877	0.02804
16.43	1880	0.54030	0.03960	1529.69	0.54624	0.04002

Table 5b (cont'd)

•	Cdl.	5Mg #3		Cdl.	5Mg #4	
Temp.	R	$^{p}\mathtt{A}$	Δ	R	$\rho_{\mathbf{A}}$	Δ
22.78	2384.7	0.6834	0.0504	1885.8	0.6734	0.0548
26.60	2727.22	0.7815	0.0512	2129.39	0.7605	0.0583
31.47	3186.76	0.9130	0.0497	2458.5	0.8781	0.0600
36.72	3698.9 ₉	1.0596	0:0469	2828.69	1.0103	0.0600
43.08	4333.64	1.2412	0.0431	3291.75	1.1759	0.0590
48.20	4850.77	1.3892	0.0400	3671.7 ₅	1.3117	0.0578
55.80	5619.3	1.6089	0.0357	4239.43	1.5	0558
65.35	6572.3	1.881.	0.0295	4945.7 ₅	1.768	0.0526
76.95	7734.8	2.214	0.0248	5808.4	2.076	0.0505
103.61	10380.3	2.969	0.0129	7768.4	2.779	0.0445
121.71	12159. ₂₅	3.478	0.0052	9082.35	3.250	0.0405
136.01	13567. ₅	3.880 -	-0.0008	10120.7	3.623	0.0374
150.75	` 15017. ₉	4.294 -	-0.0065	11188.05	4.007	0.0343
168.07	16726.35	4.782 -	0.0129	12444.1	4.459	0.0312
184.31	18340.1	5.242 -	0.0185	13629.7	4.886	0.0287
205.55	. 20460.4	5.848 -	0.0252	15186. ₅	5.447	0.0264
221.64	22077.	6.310 -	0.0295	16373.0	5.876	0.0254
238.12	23752.8	6.788 -	0.0327	17604.2	6.321	0.0259
255.70	25563. ₅	7.306 -	0.0353	18933.7	6.802	0.0272
273.18	27388.7	7.827 -	0.0368	20274.75	7.287	0.0284
297.50	29968.0	8.565 -	0.0353	22170.5	7.974	0.0344
298.35	30065.35	8.592 -	0.0335	22238.	7.999	0.0358
314.36	31806. ₅	9.090 -	0.0333	23523.3	8.465	0.0401
326.95	⁴ 33195 ₆	9.487 -	0.0305	24543.8	8.836	0.0449

Table 5b (cont'd

Cd1.5Mg #1
$$R_o = 1215.410(\pm .005) \mu\Omega$$

 $\theta = 68^{\circ} (\pm 1\frac{1}{2}^{\circ})$
 $(2/A)_{295} = .2749.8(\pm 6) \text{ cm}^{-1}$
 $B = 0.033(\pm 0.004)$
Cd1.5Mg #2 $R_o = 1352.615(\pm .005) \mu\Omega$
 $\theta = 87^{\circ} (\pm 1\frac{1}{2}^{\circ})$
 $(2/A)_{295} = .203.0(\pm 7) \text{ cm}^{-1}$
 $B = 0.031(\pm 0.004)$

Cdl.5Mg #1 $2.07\ 1215.4_{55}\ 0.4292_{33}\ 0.00001_{6}\ 1352.6_{6}\ 0.3967_{66}\ 0.00001_{4}$ 3.04 1215.6₇ 0.4293₁₂ 0.00007₄ 1353.035 0.396880 0.000107 4.18 1216.46 0.429594 0.000269 1354.32 0.397261 0.000398 $4.97 \ 1217.8_{9} \ 0.4301_{05} \ 0.00060_{8} \ 1356.6_{4}$ 0.397949 0.000912 6.11 1222.7₁ 0.4318₀₆ 0.00168₄ 1363.95 0.400093 0.002431 7.27 1232.72 0.435344 0.003882 1378.80 0.404454 0.005475 8.11 1243.6₈₅ 0.4392₂₀ 0.00621₄ 1394.68 0.409116 0.008641 10.21 1288.4 0.4550, 0.01490 1457.3° 0.4274° 0.02021 13.48 1400.20 0.03222 1604.95 0.4945 0.47082 0.04256 16.43 1533.8₆ 0.5417₃ 0.04696 1772.14 0.5198₈ 0.06116 22.78 1883.44 0.6653 0.0680 2189.88 0.6425 0.0880 26.60 2119.9₃ 0.7489 2466.5, 0.7238 0.0750 0.0972

Table 5b (cont'd)

	Cdl.	5Mg #1		Cdl.	5Mg_#2	•
Temp.	R	$^{p}\mathtt{A}$	Δ .	R	OA	Δ
31.47	2438.47	0.8616	0.0803	283" 23	0.8328	0.1045
36.72	2797.2	0.9885	0.0835	3254.53	0.9556	0.1093
43.08	3246.97	1.1477	0.0855	3778.46	1.1098	0.1126
48.20	3616.7 ₇	1.2787	0.0864	4209.97	1.2369	0.1142
55.80	4169.95	1.4748	0.0870	4856.13	1.4273	0.1157
65.35	4858.65	1.719	0.0866	5661.3	1.665	0.1162
76.95	5700.0	2.018	0.0873	6644.9	1.956	0.1174
103.61	7609.0	2.697	0.0873	8874.35	2.616	0.1183
121.71	8886.6 ₅	3.152	0.0872	10364.25	3.058	0.1186
136.01	9886.3	3.509	0.0840	11539.7	3.408	0.1189
150.75	10931.8	3.883	0.0874	12746.	3.767	0.119
168.07	12150.6	4.319	0.088	14164.0	,4,191	0.1198
184.31	13301.05	4.732	0.0893	15501.2	4.590	0.1207
205.55	14811.05	5.274	0.0919	17255.9	5.116	0.123
221.64	15962.3	5.688	0.0948	18592.8	5.517	0.1255
238.12	17155.6	6.117	0.0988	19979.1	5.934	0.129
255.70	18445.8	6.583	0.1046	21477.6	6.385	0.1344
273.18	19744.05	7.052	0.1083	22990.35	6.842	0.1385
297.50	2)583.0	7.717	0.1195	25127.9	7.488	0.1488
298.35	21645.6	7.739	0.1205	25199.85	7.510	0.1499
314.36	22895.4	8.192	0.1288	26654.0	7.950	0.1576
326.95	23884.2	8.551	0.1358	27804.4	8.299	0.1642

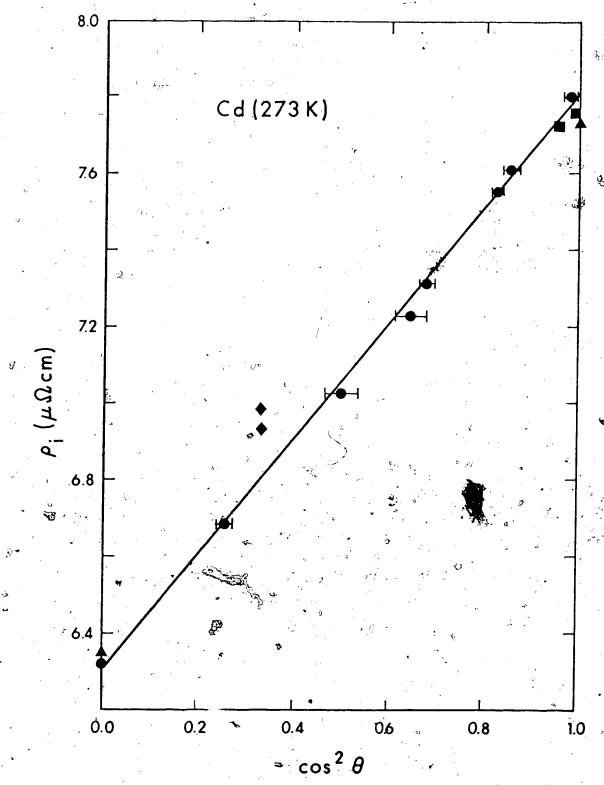
CHAPTER 5 DISCUSSION OF RESULTS

5.1 Electrical Resistivity of Pure Cadmium

We present new results for the electrical resistivity of Cd which represent the first systematic investigation since 1932. Our values for the ice point (273.15 K) resistivities are $\rho_{1||} = 7.81(\pm 0.03) \mu\Omega$ cm and $\rho_{11} = 6.30(\pm 0.03) \mu\Omega$ cm, the uncertainties being primarily due to the scatter of points on the plot of $\rho_{1273}(\theta)$ versus $\cos^2\theta$ shown in Fig. 2. The various values of ice point resistivities of Cd are summarized below:

100°			· A
Author	R ₂₉₅ /R _o	Pi 273	ρ ₁₁₂₇₃
	,	$(\mu\Omega$ cm)	· ($\mu\Omega$ cm)
this work	1x10 ⁴	7.81 03.)	6.30(±0.0 3)
Bridgman (1925)		7.68(±0.1)	6.30(±0.1)
Bridgman (1929)		7.62(±0.05)	6.32(±0.05)
Grüneisen and Goens (1923)		7.79	6.55
Grüneisen and Goens (1924)		7.79	6.54
Goens and Grüneisen (1932)		7.73	6.36 ₅
cited in Meaden (1965)	¥.	7.73	6.35

Bridgman's measurements were made at 20°C and have been adjusted to the ice point. His uncertainties have been inferred from the scatter of his points on a graph of p



versus cos²θ. All three of the studies by Grüneisen and Goens appear to be based on two or more of the same four single crystals. The values cited in Meaden can be traced back to a review article by Grüneisen (1945) who in turn attributes those values to Goens and Grüneisen but does not give recific reference.

Alderson and Hurd (1975) appear to have done a systematic study of the resistivity of Cd, but although they plot graphs of $\rho_{1||}$ and ρ_{11} as functions of temperature and they do quote a value for the high temperature limit of the ideal resistivity anisotropy $\epsilon_{1}=1.214$, they do not quote actual values for $\rho_{1||273}$ and ρ_{11273} . This is an unfortunate omission if, in fact, they did calculate accurate values. (We also note that qualitative conclusions they draw do not depend on highly accurate resistivity measurements). They do however give ice point resistivities for two of their single crystal specimens, both of which have orientations close to parallel (0 = 0°) and these have been included in Fig. 2. Recent comparable data for the axial resistivities would, however; have been valuable.

In Fig. 3, electrical resistivities at 26.34 K are plotted against $\cos^2\theta$. Here, the anisotropy ratio $a_{126}=1.470$ is considerably larger than its ice point value $a_{1273}=1.239$. Note that the positions of these points relative to the straight line is almost identical to their relative positions in Fig. 2, indicating that the

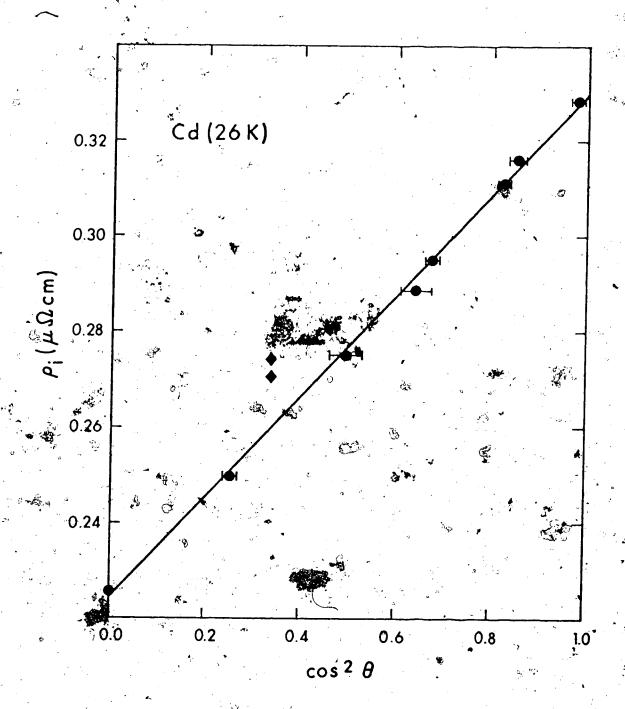


Fig. 3. Ideal resistivities ρ_i versus $\cos^2\theta$ for pure Cd at 26.34 K. •- this work, •- polycrystalline values interpolated from tables in Seth (1969).

scatter of the points about the line is largely due to random errors in the determination of orientations (shown by the horizontal error bars) as apposed to random errors in the sistivity values:

has been plotted against $\rho_{\mbox{1,273}}$ for each pure Cd specimen in Fig. 4 for two reasons:

First, this graph also helps to ascertain whether or not there are significant random errors in the electrical resistivities. If the resistivities are accurate, all points should lie on the same straight line independent of their orientation determinations. (Actually, the very small change of orientation on the mal contraction caus the line to be slightly concave upwards, the maximum, deviation from linearity being approximately equal to the width of the Tine). The position along the line should by proportional to $\cos^2\theta$, so that an error in θ would cause a point to lie in a slightly different position than expected, but still on the line. Because of the different anisotropies however, random errors in the resistivities produce a scatter of the points about the land . Changing an l/A value by 1% for example would cause a point to move about 1.6 mm off the line in Fig. 4. low scatter of our points indicates that the random errors. in the resistivitles were 0.5% or less, as expected. Also, allowing for the probable error in determining θ 's, all specimens were in their expected positions along the

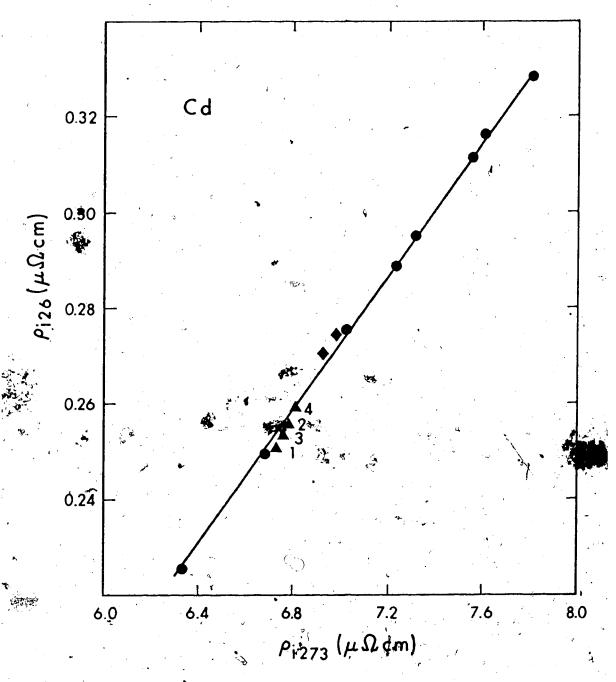


Fig. 4. Ideal resistivities at 26.34 K (ρ₁₂₆) versus ideal resistivities at 273.15 K (ρ₁₂₇₃) for pure Cd. •- this work, •- polycrystalline values from Seth (1969), •- Δ₁, •- Δ₂, •- Δ₃ and •- Δ₄ are calculated polycrystalline values using equations 5.1, 5.2, 5.3 and 5.4 respectively.

line except Cd #7 which was just outside the expected range.

Secondly, Fig. 4 is a useful tool for comparing single crystal elastrical resistivities to polycrystalline values. Alstad, Colvin and Legvold (1961) tested four different formulas comparing $\rho_{\rm poly}$ (= $1/\sigma_{\rm poly}$) to $\rho_{\rm poly}$ (= $1/\sigma_{\rm poly}$) and $\rho_{\rm poly}$ (= $1/\sigma_{\rm poly}$):

$$\sigma_{\text{poly}} = (1/3)\sigma_{\text{poly}} + (2/3)\sigma_{\text{poly}}$$
 (5.1)

$$\rho_{\text{poly}} = \frac{\left[\rho_{1}(\rho_{||} - \rho_{1})\right]^{\frac{1}{2}}}{\tan^{-1}\left\{\left[(\rho_{||} - \rho_{1})/\rho_{1}\right]^{\frac{1}{2}}\right\}}$$
(5.2)

$$\sigma_{\text{poly}}^{\sigma_{\text{poly}}} = \{\sigma_{1} + [\sigma_{1}(8\sigma_{1} + \sigma_{1})]^{\frac{1}{2}}\}$$
 (5.3)

$$\rho_{\text{poly}} = (1/3)\rho_{1} + (2/3)\rho_{1}.$$
 (5.4)

Although they conclude that for highly anisotropic Yttrium $(\rho_{11}/\rho_{11}) = 2.07$ at 300 K) Eq. 5.4 is the best, the purity of their specimens was not good (ρ_{300}/ρ_0) ranged from 6 to 28). It would be worthwhile to repeat this test with a metal for which high purity material is available, such as Sn, even though its anisotropy ratio $a = \rho_{11}/\rho_{11}$ is not as extreme.

formulas with our values of ρ_{\parallel} , and ρ_{\perp} at both 273 K and 26 K. Those four points have been plotted in Fig. 4, as

well as points for Seth's (1969) two polycrystalline Cd specimens. Although more valid comparison would be possible by measuring the polycrystal and single crystal resistivities simultaneously (ρ_{poly26} was determined by interpolating resistivities Seth has given in tables), both of Seth's specimens appear to have preferred orientations closer to parallel than expected for any of the four formulas.

If we assume that Eq. 5.4 is correct, then a polycrystalline specimen would have the same resistivity as a single crystal with an orientation such that $\cos^2\theta_{293}$ (and $\cos^2\theta_{26}=0.338$). The resistivities of Seth's specimens have therefore been plotted in Figs. 2 and 3 using the above values for the abscissa. These points all lie significantly above the line, indicating again preferred orientations closer to parallel than expected.

We ultimately wish to compare our values of DMR in single crystals to those of Seth and Woods (1970) for polycrystalline specimens. Because Seth and Woods suspected the unusual behaviour in their Cd and Cd-Mg specimens may be due to different preferred orientations in different specimens, it is valuable to determine whether or not preferred orientations do exist.

5.2 Electrical Resistivity of Cd-Mg Alloys

The electrical resistivity of single crystals of an alloy with fixed concentration should also vary as $\cos^2\theta$. Figs. 5 and 6 show the good fits of the ice point resistivities and the residual resistivities to $\cos^2\theta$ for $\rho_{\Lambda_{\Lambda}}$ is also plotted against ρ_{Λ} the Cd0.76Mg specimens. for these specimens in Fig. 7 and as in Fig. 4 for pure Cd, a straight line is expected providing the resistivities have no large random errors and in the case of alloys providing the impurity concentration does not vary randomly among specimens. Appoint is plotted for Seth's Cd0.75Mg polycrystalline specien and it is considerably below the line. This is caused largely if not totally by its lower Mg concentration (~ 0.73 at. % based on the fit to x(1-x)of data in Table 1) compared to our Cd0.76Mg specimens (~ 0.78 at. %, Table 2). An increase in Mg concentration would move that point primarily vertically although also. slightly to the right on Fig. 7. With the adjustment for concentration, Seth's point lies to the right of the three points (merangles) calculated using Eqs. 5.1, 5.3 and 5.4. indicating again a preferred orientation closer to parallel than expected. This preferred orientation is confirmed in Fig. 5 where the polycrystalline point lies above the line for the single crystals.

The residual resistivities for the Cdl.5Mg single crystals (which have not been plotted) do not fit well on

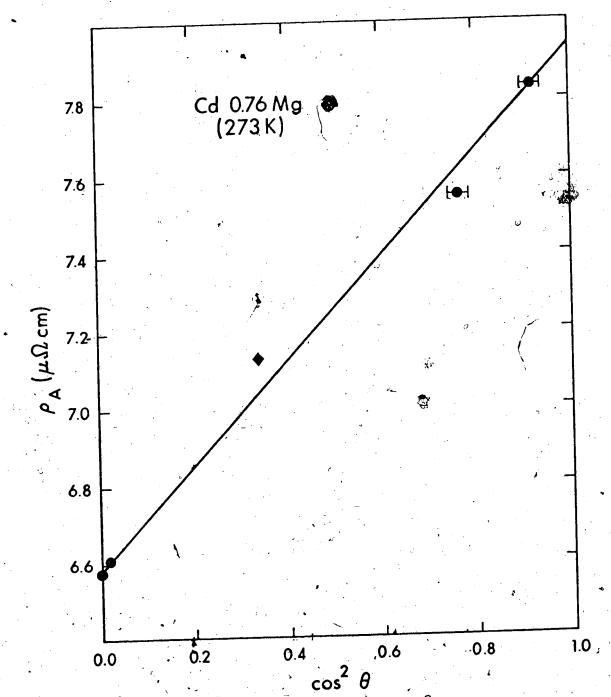


Fig. 5. Alloy resistivities ρ_A versus cos²θ for Cd0.76Mg at 273.15 K. •- this work, •- polycrystalline value from Seth (1969) for Cd0.75Mg.

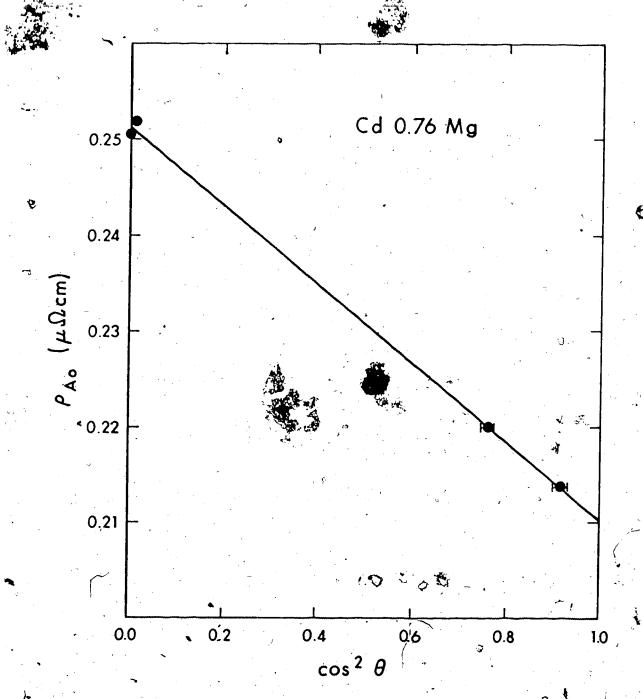


Fig. 6. Alloy fasidual resistivities ρ_{Ao} versus $\cos^2\theta$ for Cd0.76Mg. •- this work, •- polycrystalline value from Seth (1969) for Cd0.75Mg.

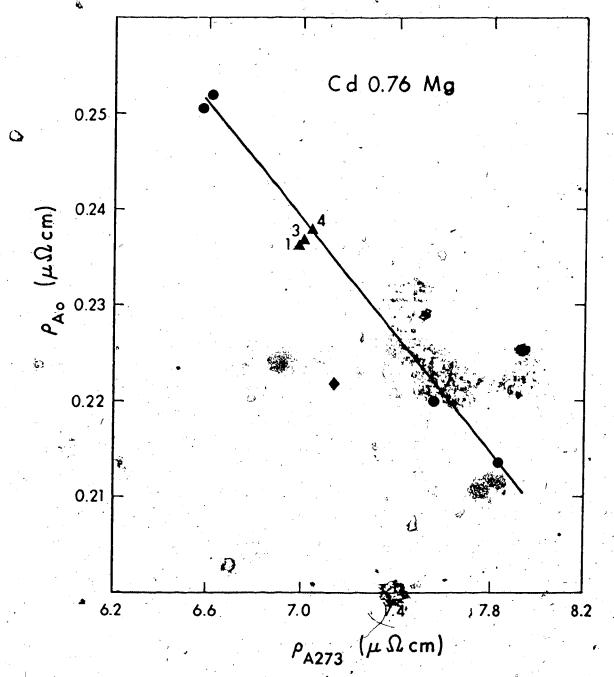


Fig. 7. Alloy residual resistivities (ρ_A) versus alloy resistivities at 273 K (ρ_{A273}) for Cd0.76Mg.
← this work, ← polycrystalline values from Seth (1969) for Cd0.75Mg, ♠₁, ♠₃ and ♠₄ are calculated polycrystalline values using equations 5.1, 5.3 and 5.4 respectively.

a plot against cos²θ, probably because of variation from specimen to specimen of the Mg concentration in solid solution. However, the fit of the Cdl.5Mg ice point resistivities (which are relatively weakly dependent on concentration) to cos²θ is good, similar to Fig. 5 (the Cdl.5Mg plot is also not shown explicitly). The position of Seth's Cdl.5Mg polycrystalline specimen, adjusted slightly for concentration differences, is again above the line for the Cdl.5Mg single crystals again indicating a preferred orientation somewhat closer to parallel than expected.

5.3 Resistivity Anisotropy Ratios

For pure Cd, the ideal resistivity anisotropy ratio $a_1 = \rho_1 | | / \rho_{11}$ was calculated at all temperatures as described in Sec. 4.1.5. As Rowlands, Stackhouse and Woods (1975) have shown, the fit of these data with the theoretical calculations of White and Carbotte (1975) for 2n (which has a similar c/a ratio and Brillouin zone structure to Cd) as good. Fig. 8 also shows this comparison, this time including points plotted from three different experimental runs and including the correction to $f = \ell/A$ for thermal expansion (this correction leaves a_{293} unchanged while increasing a_{26} by about 2.4% but does not change the basic shape of the curve). The temperature dependence of a_1 agrees well with values measured by Goens

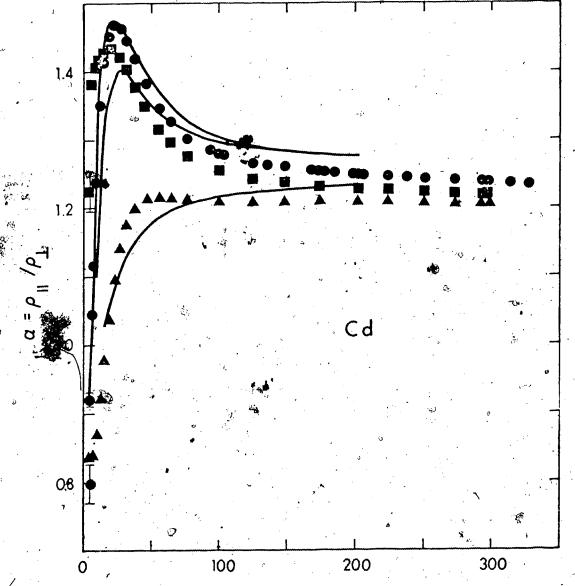


Fig. 8. Resistivity anisotropy ratios $a = \rho_{\parallel}/\rho_{\perp}$ versus température T. $\bullet - a_1 = \rho_{\parallel}/\rho_{\parallel}$ for pure Cd, $\bullet - a_A = \rho_{A\parallel}/\rho_{A\perp}$ for Cd0.76Mg, $\bullet - (\rho_A)/T^ \rho_{A\parallel}/\rho_{A\perp}T^-\rho_{A\perp}O$ for Cd0.76Mg. $\rho_{O} \sim \rho_{\perp}T$ at 6 K for pure Cd, $\rho_{AO} \sim \rho_{\perp}T$ at 23 K for Cd0.76Mg. The solid curves are the theoretical calculations by White and Carbotte (1974) for (from top to bottom) (a) $a_1 = \rho_{\parallel}/\rho_{\perp}T$ for pure Zn (b) $(\rho_A|T^-\rho_A|O)/(\rho_{A\perp}T^-\rho_{A\perp}O)$ for a Zn alloy with $\rho_{AO} = 0.5\mu\Omega$ cm and (c) $a_{AT} = \rho_{A\parallel}/T^-\rho_{A\perp}T$ for the same Zn alloy.

and Grüneisen (1932) at 21.2 K, 83.2 K and 273.2 K as well as values of Alderson and Hurd (1975) from 3 K to 590 K.

Our measurements show reasonable qualitative agreement with the predictions of Case and Gueths (1970) (see Sec. 2.1) for any axial metal except at the lowest temperatures where the measured values of $a_{\rm iT}$ drop well below ' $a_{\rm i\infty}$. Indeed, Case and Geuths' measurements on Sn lacked the accuracy medessary to test their own low temperature prediction.

White and Carbotte (1974) also calculated the resistivity anisotropy ratio for dilute Zn alloys. anisotropy curves for a Zn alloy with a residual resistivity of $0.5\mu\Omega$ cm and our experimental anisotropy ratios for Cd0.76Mg with residual resistivites of \sim 0.23 $\mu\Omega$ cm are also shown in Fig. 8 both with and without the residual resistivities subtracted from the total resistivities. The axial resistivities for Cdp. 76Mg were determined using the method described in Sec. 4.1.5 for pure Cd. straight lines in Figs. 5 and 6 pass through the point for Cd0.76Mg #8 and half way between the points for Cd0.76Mg #3 and Cd0.76Mg #5. The vertical intercepts of these lines determine the axial resistivities. temperatures, $\rho_{A||T}$, $\rho_{A\perp T}$ and hence $\alpha_{AT} = \rho_{A||T}^*/\rho_{A\perp T}$ and $(\rho_{A||T} - \rho_{A||O})/(\rho_{A\perp T} - \rho_{A\perp O})$ were calculated assuming the same fit for these three specimens.

The agreement between experimental and theoretical

anisotropy ratios is not as good for the alloys as for the pure metals. For example the maximum value of $(\rho_{\parallel} - \rho_{o})/(\rho_{\perp} - \rho_{o})$ occurs at a slightly lower temperature than $\alpha_{\rm imax}$ for the Cd alloys (experiment) but at a slightly higher temperature for the Zr alloys (theory). Admittedly, White and Carbotte have obtained an isotropic residual resistivity which is not the case for Cd0.76Mg alloys (Fig. 6), so one cannot expect to compare these curves in too much detail.

Note that the temperature dependence of all three calculated anisotropies is largely independent of the fits of ρ to $\cos^2\theta$ shown in Figs. 2, 3, 5 and 6. Errors in ρ_{\parallel} and/or ρ_{\perp} could affect the absolute values of the anisotropy ratios but they would not affect the shape of these curves. Even the section of the maximum of $(\rho_{A}||T-\rho_{A}||o)/(\rho_{A}|T-\rho_{A}|o)$ (which is the same as $(\rho_{\parallel}||T+\Delta_{\parallel}||T)/(\rho_{\parallel}||T+\Delta_{\parallel}|T)$) relative to α_{lmax} will be roughly independent of these fits (Figs. 9 and 10 in the next section show that Δ_{\parallel} and Δ_{\perp} are not strongly dependent on concentration and hence ρ_{0}).

White and Carbotte emphasize that the anisotropy curves for the metal and $(\rho_{\parallel} - \rho_{0})/(\rho_{\perp} - \rho_{0})$ for the alloys are not coincident, indicating that DMR exist. Because they are so sensitive to small changes in ρ , DMR offer a particularly rigorous test of theoretical calculations. DMR are discussed in the following section.

5.4 Deviations from Matthiessen's Rule

Deviations from Matthiessen's rule (DMR or Δ) have been calculated for each single crystal alloy specimen as described in Sec. 4.1.5 and are plotted against temperature in Fig. 9 for Cd0.76Mg specimens and in Fig. 10 for Cd1.5Mg specimens. The bold haken lines enveloping the triangles in Fig. 9 indicate the real ble error. Because DMR are calculated by subtracting countities which are nearly equal ($\rho_{1T} \simeq \rho_{AT} - \rho_{AO}$), relatively small errors in ρ_{AT} , ρ_{AO} and ρ_{1T} produce much larger relative errors in Δ .

The values of Δ at 273K for all eight alloy crystals are plotted against $\cos^2\theta$ in Fig. 11. Because ρ_{AT} , ρ_{AO} and ρ_{iT} are all linear in $\cos^2\theta$, Δ should be linear in $\cos^2\theta$ as well (Eqs. 2.8a and 2.8b). Although greater accuracy would make these results more convincing, Fig. 11 does indeed show that linear relationship with the line for the Cdl.5Mg alloys slightly higher than the line for the Cd0.76Mg alloys. Because Δ was evaluated separately for each alloy specimen, the fit of Δ to $\cos^2\theta$ will not depend greatly on a good fit of ρ_{AO} to $\cos^2\theta$ (which is not good for Cdl.5Mg).

At the lowest temperatures, T^210K , Δ follows a power law, $\Delta \propto T^n$ and n was found to be $5.25(\pm 0.2)$ for the parallel orientation and $4.75(\pm 0.2)$ for the perpendicular orientation. These values are consistent with the value

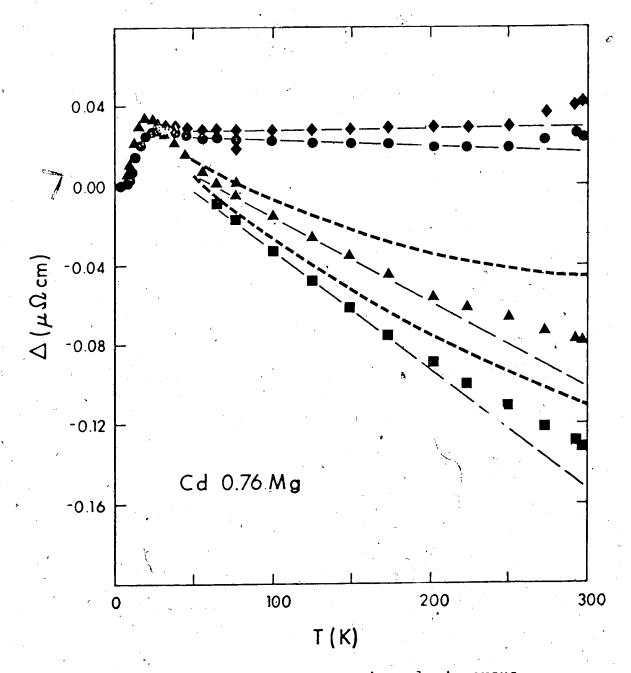
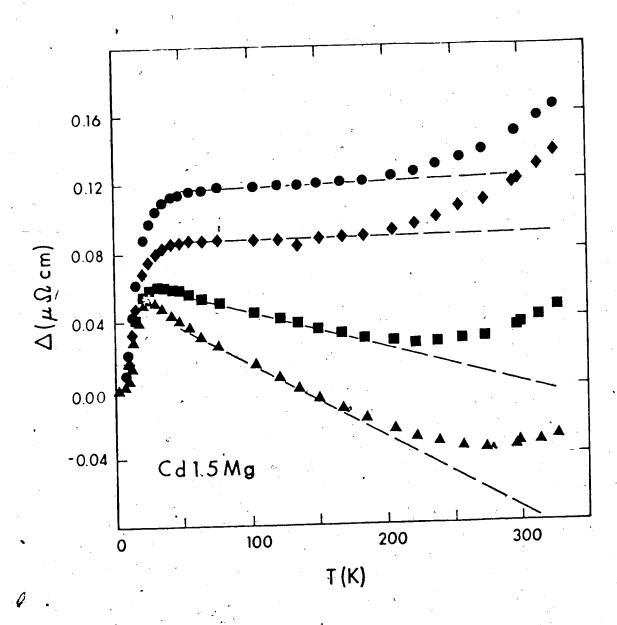


Fig. 9. Deviations from Matthiessen's rule Δ versus temperature T for Cd0.76Mg of orientations:

• - θ = 89½°, • - θ = 83½°, • - θ = 29° and

• - θ = 16½°. The bold dashed lines forming an envelope on either side of the triangles represent probable errors in absolute values of Δ.



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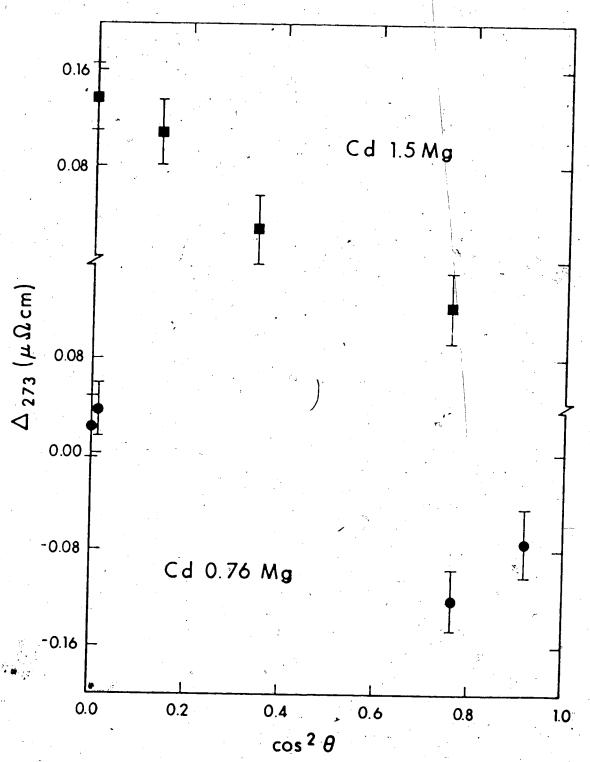


Fig. 11. Deviations from Matthiessen's rule at 273 K (Δ_{273}) versus $\cos^2\theta$ for Cd0.76Mg (•) and Cd1.5Mg (•).

found by Seth (1969) of $n \sim 5$ for Δ of polycrystalline specimens.

The ideal resistivities of pure Cd were also found to have power law dependence in the same temperature range, $\rho_{1} \propto T^{n} \text{ where } n = 5.7(\pm 0.2) \text{ for } \rho_{1} | \text{ and } n = 5.0(\pm 0.2) \text{ for } \rho_{1} | \text{ These values are consistent with those of 5.9 and 5.0 found by Alderson and Hurd (1975), although Alexandrov and D'Yakov (1963) find <math>\rho_{1} \propto T^{5}$ for both crystal orientations. Seth (1969) reports an exponent n = 4.8 for polycrystalline pure Cd specimens.

At somewhat higher temperature T \sim 25 K there is a hump in Δ (Figs. 9 and 10). The hump occurs where $\rho_{\rm iT} \sim \rho_{\rm Ao}$ and is more pronounced for the dilute alloys. Neither the hump nor the power law dependence is unusual and both have been discussed briefly from a theoretical point of view in Sec. 2.2. These, however, are not the features of central interest in this thesis.

At high temperatures, Δ is expected to be linear in T and may be either positive or negative (Bhatia and Gupta, 1969). Figs. 9 and 10 do show a linear region from about 75 K to 200 K but at higher temperatures yet, the slopes of the Δ^2 T curves increase to more positive values. Damon and Klemens (1965) predicted this type of feature would arise as a result of local phonon modes in binary alloys where the solute atoms are much lighter than the solvent atoms. They searched for this effect themselves

in gold alloys but failed to see it. Seth and Woods (1970) show a similar increase in slope of their Δ -T curves at about 200 K for Cd-Mg polycrystalline specimens. Because of their concern for possible preferred orientations, however, they did not interpret this behaviour as arising from local modes.

The increase in slope should occur at $\sim 0_{\rm o}/2$ where $\theta_{\rm o} \simeq ({\rm M_i/M_o})^{1/2} \theta_{\rm D}$ (see also Eqs. 2.10 and 2.11). For Cd, $\theta_{\rm D} \simeq 170$ K, so $\theta_{\rm o} \simeq 365$ K and the increase in slope due to a local mode would be expected at about 180 K. Indeed, this agrees roughly with our experimental results.

Local mode frequencies (and hence θ_0 's) parallel and perpendicular to the c axis should be proportional to the square roots of the atomic force constants which are quite anisotropic in Cd. Because the elastic constants c_{33} and c_{11} are proportional to the atomic force constants, local mode characteristic temperatures θ_0 should be roughly proportional to the square roots of the elastic constants as well. Indeed, the ratios $\theta_0 | \theta_0 | = 175/250 = 0.70$ from Fig. 9 - this effect is not as pronounced in Fig. 10)

^{*}The elastic constants, also depend on the lattice parameters, a and c. In a tetragonal lattice, for example, $C_{11} = k_1/c$ and $C_{33} = k_1/c/a^2$ where k_1 and k_1/c are the atomic force constants and we assume only nearest neighbour interactions. Because the c/a ratio for Cd (1.889 at 293 K) is only 14% greater than the close-packed value (1.633) the anisotropy of the elastic constants $C_{11}/C_{33} = 2.35$ must arise primarily from the anisotropy in the atomic force constants.

and $\sqrt{c_{33}}/\sqrt{c_{11}}$ (= $\sqrt{4.9(\pm0.2)}/\sqrt{11.5(\pm0.5)}$) = 0.65(±0.03) from Alexandrov and Ryzhova (1961) are relatively close. Thus, the relevant force constant for the local mode resistivity is in the direction of the applied electric field. This is expected since the probability of scattering an electron from state \vec{k} to \vec{k}' , $P(\vec{k}, \vec{k}') \propto |\vec{u} \cdot (\vec{k} - \vec{k}')|^2$ where \vec{u} is the ionic displacement (see Ziman, 1969, p. 173).

The magnitude of the increase in slope is roughly proportional to Mg concentration in this work and in that of Seth and Woods (1970). This too is expected. We make a preliminary estimate of the local mode resistivity above θ_0 by multiplying the ideal resistivity ρ_1 of the host by the atomic fraction of light impurity atoms x:

$$\Delta_{4} \sim x \rho_{1} \tag{5.5}$$

Estimates of Δ_4 based on this formula are in rough agreement with experiments.

Thus, electron scattering from a local mode can account for the magnitude, the concentration dependence, the temperature and the anisotropy in temperature of an otherwise unexplained feature of the resistivity of Cd-Mg alloys. Although Damon and Klemens (1965) failed to see this effect in gold alloys, the ideal resistivity of gold is much lower than cadmium's so that according to Eq. 5.5, they were looking for a much smaller effect. Secondly,

for their allows $\rho_{iT} \simeq \rho_{Ao}$ at a temperature much higher and closer to $\theta_{o}/2$ where Δ_{μ} becomes significant. Under these conditions, Δ_{μ} could have been masked by other contributions to Δ discussed in Sec. 2.2 (e.g. the hump in Δ is often located at temperatures where $\rho_{iT} \sim \rho_{Ao})$. We suggest further experiments to search for this local mode effect in other alloy systems.

We emphasize that the temperature dependence of our Δ -T curves (Figs. 9 and 10) is largely independent of errors in ℓ/A . These errors do not significantly affect the shape of the Δ -T curves and in particular, they do not affect the slope change which we associate with local modes.

Looking again at Figs. 9, 10 and 11, we also see qualitative agreement of our data with both the theoretical calculations of Toussaint and Pecheur (1973) for single crystals and with the experimental Δ -T curves of Seth and Woods (1970) for polycrystalline Cd-Mg. Seth and Woods did not expect the high temperature slopes of their Δ -T curves to be negative (see Ch. 1) and suggested their specimens may have preferred orientations. Although it now appears that their specimens did have preferred orientations (see Secs. 5.1 and 5.2), both pure and alloy specimens appear to have roughly the same preferred orientation, somewhat closer to parallel than expected, and consequently their Δ -T curves are roughly valid for that preferred orientation. Indeed, the similar shapes and magnitudes

of their curves to Figs. 9 and 10 confirms this interpretation.

In the meantime, Toussaint and Pecheur calculated Δ_3 in Cd-Mg single crystals which we re negative at high temperatures, thus partially explaining Seth and Woods' results, and were an order of magnitude larger in the c direction than the a direction. Although they appear to have used pure metal pseudopotential matrix elements W_{Cd} and W_{Mg} in their calculations as opposed to pseudopotential matrix elements for the dilute alloy, the agreement of their theory with our experiments is remarkably good.

CHAPTER 6

CONCLUSIONS

We have measured the electrical resistivities from 2 K to 300 K for eight Cd single crystals and twelve $\underline{\text{Cd-Mg}}$ single crystals including three different concentrations. The measured densities of our specimens were typically 2½% below the accepted x-ray densities. This we attribute to small bubbles in the specimens and we have made an appropriate correction to obtain the resistivity values. The ice point resistivities for Cd were found to be $\rho_{\parallel}=7.81(\pm0.03)\mu\Omega$ cm and $\rho_{\perp}=6.30(\pm0.03)\mu\Omega$ cm.

The resistivity anisotropy ratio $a = \rho_{\parallel}/\rho_{\parallel}$, for Cd as a function of temperature is in good qualitative agreement with the simple theory of Case and Gueths (1970) except at the lowest temperatures where a falls well below the predicted value of a_{∞} and where Case and Gueths' own work lacked the accuracy to test their low temperature prediction. That even a partial agreement exists is surprising, cor ideang Case and Gueths' simplified model of the Fermi surface and their complete neglect of any effects due to anisotropy in the phonon spectrum. A better fit is to the calculated curve of White and Carbotte (1974) for Zn, perhaps a permissible comparison because of the similar c/a ratios and Fermi surfaces of Cd and Zn. The anisotropy ratios for the alloy specimens do not agree as well

as for the pure samples, but White and Carbotte have obtained isotropic residual resistivities in their \ calculations whereas experimental residual resistivities for Cd0.76Mg alloys are not isotropic.

Deviations from Matth essen's rule were calculated for the Cd-Mg single crystale in the hope of clarifying the peculiar high temperature results in the Cd-Mg polycrystals of Seth and Woods (1970). By comparing their polycrystal resistivities to ours for single crystals, we have shown that the polycrystals probably did_have preferired orientations but the preferred prientations for both . pure and alloy specimens were very similar. Their DMR are consequently comparable with our single crystal DMR. Our high temperature DMR are in good qualitative agreement with theoretical calculations by Toussaint and Pecheur (1973). In addition, the increase in slope of the $\Delta-T$ curves at about 200 K show all the salient but otherwise unexplained features for electron spattering from a local phonon mode. Although Damon and Klemens (1965) predicted and sought for this effect in gold alloys, it has not previously been recognized. In retrospect, Jeth and Woods! results can also be explained in terms of Toussaint and Pecheur's calculations plus the effect of the local mode.

We emphasize that errors in the geometrical shape factors L/A for our specimens and in the more than for bubbles do not significantly affect the temperature

dependence of either hand DM . In particular, they do not affect our inclusions about the anisotropy ratio non do they affect our conclusions about the local mode resistivity.

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NOTATION

Below is a list of frequently used symbols and definitions in this thesis:

- θ (lower case theta) specimen orientation, the angle between c axis and the specimen axis.
 - $\boldsymbol{\theta}_{T}$ denotes explicitly the dependence of orientation on temperature, T.
 - $\theta_{\rm O}$ orientation as T + 0 K
 - θ_{293} orientation at T = 293 K
- 0 (upper case theta) characteristic temperature
 - Θ_{D} Debye temperature
 - 0 Local mode characteristic temperature
 - O | | Characteristic temperature for vibrations parallel to the c axis.
 - θ_1 Characteristic temperature for vibrations perpendicular to the c axis.
- ω frequency, or characteristic frequency, appears with the same subscripts as Θ above.
- ρ electrical resistivity
 - $\rho(\theta)$ denotes explicitly the dependence on orientation. Up to three subscripts are also used to denote explicitly the dependence on composition (ρ_{1}, ρ_{A}) , axial orientations $(\rho_{||}, \rho_{1})$ and temperature $(\rho_{T}, \rho_{0}, \rho_{273})$ in that order. Up to three subscripts may be included in a single symbol (e.g. $\rho_{1||T}$).

 $(\rho_{i,i})$ - the resistivity tensor

 ρ_1 (often appearing as $\rho_{1T})$ the "ideal" resistivity of a high purity metal after its small residual resistivity has been subtracted.

 ρ_P - the total resistivity of a "pure" metal specimen including the residual resistivity, therefore ρ_{im} = ρ_{PD} - ρ_{PO}^* .

 $\rho_{\mbox{\scriptsize A}}$ - the total resistivity of an alloy specimen including the residual resistivity.

 $\rho_{\rm T}$ - denotes explicitly the dependence of resistivity on temperature

 ρ_{273} - resistivity at T = 273 K.

 $\rho_{_{\rm O}}$ - extrapolated residual resistivity at T = 0 K

 $\rho_{\mbox{\footnotesize{poly}}}$ - resistivity of a polycrystalline specimen.

 ρ_{\parallel} = $\rho(0^{\circ})$ - resistivity parallel to the c axis.

 $\rho_{12} = \rho(90^{\circ})$ - resistivity perpendicular to the c axis.

 ρ_{meas} - the measured value of resistivity

 $\boldsymbol{\rho}_{m}$ - the resistivity of a mixture

We denote similarly in σ , Δ , α , R, f = ℓ/A and L the dependence on composition, orientation, and/or temperature. σ - electrical conductivity

 Δ - the total "deviation from Matthiessen's rule" (DMR) for an alloy specimen

 Δ_3 - the contribution to Δ due to the interference term

 $\Delta_{\,\,\underline{\boldsymbol{\mathcal{1}}}}$ - the contribution to Δ due to localized phonon modes

 $a = \rho_{\parallel}/\rho_{\perp}$ - anisotropy ratio

 a_{∞} - the extrapolated value of a as T + ∞ .

 a_{max} - the maximum value of a.

R - electrical resistance

 R_s - resistance of a standard resistor.

Cd0.76Mg #5 - specimen number 5 made from the master alloy of host Cd with 0.76 atomic percent Mg.

Cd-Mg - a dilute binary alloy of host Cd with impurity Mg.

Cd-Mg - a binary alloy of Cd and Mg.

- x concentration, the atomic fraction of solute metal in a binary alloy (in eq. 2.8 only, c is used for concentration).
- B "Bubble factor", the fraction of the total specimen
 volume occupied by bubbles or voids.
 B also denotes one of the constituents in a

binary (A-B) alloy.

- c c direction or c axis the crystal direction (axis)

 perpendicular to the hexagonal planes of six-fold

 symmetry.
 - c the lattice parameter in the c direction.
- a a direction or a axis a crystal direction from an atom towards a nearest neighbour atom in the same hexagonal plane.
 - a the lattice parameter in the a direction.
- $f = f_{k}^{+}$ electron distribution function (appears in Chapter 2 only).

- f = l/A geometrical shape factor for specimens (appears in Chapters 3 and 4)
- 2 the length between potential contacts on a specimen
- ℓ' the length of a specimen after it is cut for weighing $(\ell' \simeq \ell)$.
- L appears in the form (L_T/L_{293}) which represents the fractional thermal contraction (or expansion), usually in a given direction. The subscripts $||\cdot|$, and $||\cdot|$ denote orientation.
- \dot{A} usually in the form (l/A), is the average cross-sectional area of a specimen.
 - -as a subscript e.g. ρ_{AT} denotes an alloy specimen. -A | | and A | in Chapter 2 only denote areas on the
 - Fermi surface.
 - also denotes one of the constituents in a binary (A-B) alloy.
- ${\rm M_{\mbox{\scriptsize i}}}$ and ${\rm M_{\mbox{\scriptsize o}}}$ masses of the host and impurity atoms respectively in a dilute binary alloy.
- \vec{E} electric field. E_i i = 1,2,3 are components of \vec{E}
- \vec{J} electric current density. J_i \vec{i} = 1,2,3 are components of \vec{J}
- between electric field \vec{E} and current density \vec{J} anisotropic crystals.

appears in Appendix 2 only.

- k elet in wave number
- k (k) nearest neighbour atomic force constants

C₁₁ (C₃₃) - elastic stiffness constants.

Other less frequently used symbols are defined in the text.

TRANSVERSE ELECTRIC FIELD IN ANISOTROPIC METALS

In the long thin specimens used for resistivity measurements, the electric current density \vec{J} is uniform and parallel to the specimen axis except near the current contacts. Even in metals with the simplest anisotropic crystal structures (hexagonal, tetragonal, and trigonal), the electric field, \vec{E} , is parallel to \vec{J} only for specimens with parallel ($\theta = 0^{\circ}$) or perpendicular ($\theta = 90^{\circ}$) orientations. In general, for a specimen of orientation θ , the components of \vec{E} can be found using:

$$\begin{pmatrix}
E_1 \\
E_2 \\
E_3
\end{pmatrix} = \begin{pmatrix}
\rho_1 & 0 & 0 \\
0 & \rho_1 & 0 \\
0 & 0 & \rho_{||}
\end{pmatrix} \begin{pmatrix}
J\sin\theta \\
0 \\
J\cos\theta
\end{pmatrix} (A2.1)$$

The angle ϕ between \vec{J} and \vec{E} is

$$\phi = \theta - \tan^{-1} \left[(\rho_{\perp}/\rho_{\parallel}) \tan \theta \right]$$

$$= \theta - \tan^{-1} \left[(\tan \theta)/\alpha \right]$$
(A2.2)

For a cadmium single crystal ($\rho_{\parallel}/\rho_{\perp}=1.237$ at 295K) of orientation $\theta=45^{\circ}$, $\phi=6.05^{\circ}$. The transverse component of \vec{E} is not negligible and could be measured.

For a given orientation and current density, the transverse electric field ($\dot{\mathbb{E}}\sin\phi$) depends only on the anisotropy ratio $a=\rho_{\parallel \parallel}/\rho_{\perp}$ and is approximately proportional to (a-1). Tables relating ϕ and a are easily constructed. The transverse electric field is thus a measure of the anisotropy ratio. Since an average resistivity

$$\rho(\theta) = \rho_1 \cos^2 \theta + \rho_1 \sin^2 \theta \qquad (A2.3)$$

can be measured in the conventional method using the longitudinal field (Ecos ϕ), both ρ_{\parallel} and p_{\perp} can be found by two measurements on the same specimen.

The specimen geometry suggested for this type of measurement is a rectangular prism with \$\mathbb{2} > \mathbb{W} > \mathbb{h}\$, typically 20 cm x 1 cm x 0.2 cm, and with the c-axis lying i. the \$\mathbb{l} \mathbb{W}\$ plane. Such specimens could either be cut from larger crystals or grown from seeds in molds of the desired shape. In order that the transverse potential contacts do not sample a small part of the longitudinal potential difference, it will be important that these contacts are located accurately opposite each other. An uncertainty of \$\pm 0.02\$ cm would produce an uncertainty in \$a\$ of \$\pm 19\mathbb{H}\$ for a cadmium crystal of orientation \$450\$ and the above typical geometry. Unlike Hall effect measurements where the external magnetic field can be turned off while the

unwanted longitudinal potential is adjusted to zero, there is no way of "turning off" the transverse field without turning the longitudinal field off too. A specimen holder could, however, be checked or calibrated using an isotropic metal. This method of resistivity measurement does offer some advantages, particularly for anisotropic alloy crystals where concentrations may vary among specimens.

SUGGESTIONS FOR FUTURE RESISTIVITY MEASUREMENTS

The largest errors in this work are in the measurements of $(\ell/A)_{295}$ which are the culmination of many small errors. Even though the improvement in accuracy due to the suggestions below may seem almost trivial, maximum precision at all stages is vital in obtaining Δ with reasonable accuracy.

(1) Specimen diameters should be tripled to about 3 mm. Size effects at the lowest temperatures would be less important, the accuracies of the cross-sectional areas determined by weighing and by micrometer measurements would be increased and specimens would be both easier to handle and stronger. Although sharper x-ray diffraction patterns for thick specimens are probably due in part to the smaller radius of curvature, I suspect there is also less strain in thick specimens. Whatever the cause, the accuracy of the orientation determinations could be increased somewhat. Although the resistance and thus the IR drop is inversely proportional to cross-sectional area our voltage sensitivity has increased by an order of magnitude with the acquisition of the current comparator since Seth and Woods' (1970) work so that we can afford to Olose an order of magnitude in the value of R. In fact, the current could also be tripled without increasing the

heat dissipation I²R in the specimens themselves, beyond that presently dissipated, and consequently, the loss in voltage IR would only be a factor of three.

- holder which allows free expansion as well as contraction and the current connections should continue to be soldered to the specimens. Potential contacts, however, should be redesigned to be spring-loaded, such as the knife-edge contacts shown by Case and Geuths (1970). These would ensure electrical contact throughout the run and would hopefully avoid the small resistance changes we occasionally observed due to thermal cycling. Knife-edges transverse to the specimen length are probably preferable to point contacts as the indentations they make in the specimen are likely to produce smaller uncertainties in £.
- (3) Alloy specimens should be dilute with impurity concentrations of about 1 atomic percent or less. This should both, reduce uncertainties in densities (which in Cd-Mg, for example, is fairly strongly dependent on concentration which, in turn, is difficult to determine with great precision) and minimize the possibility of atomic ordering in the lattice.
- (4) Specimens should be cut prior to weighing with a spark-cutter, for example, to maximize the accuracy of £'.
- (5) Densities of all specimens should continue to to be measured and compared to x-ray values to determine

the size of the bubble factor, if any. Efforts should be made to reduce or eliminate bubbles. In spite of rapid evaporation, it would probably be worth trying Bridgman's (1925) technique of washing molten metals zback and forth under a vacuum to get rid of occluded gard. Although the mold material may not play a role in this process, bubble factors should be compared for specimens grown in glass and graphite molds. It is also possible that graphite molds produce less strain in the specimen. Alderson and Hurd (1975) measured 3 mm diameter specimens grown in graphite molds up to 587 K with only a small change in resistivities on returning to room temperature. Alexandrov (1963) also used graphite molds for Cd even though glass molds and hydrofluoric acid were used for other metals (In, Pb, Bi) in the same study. If glass molds and HF are used, the acid should not be used until excessive amounts of time are required to dissolve the glass and the specimens should be rinsed thoroughly after the HF 'etch' o In preliminary runs, some specimens show an unusual decrease in resistivity below about 4 K which we attribute to a black residue left on some specimens after the HF etch.

CHANGE OF SINGLE CRYSTAL ORIENTATION DUE TO ANISOTROPIC THERMAL CONTRACTION

In Figure 12(a) it can be seen that:

$$\tan \theta_{293} = n_a a_{293} / n_c c_{293}$$
 (A4.1)

where θ_{293} is the angle between the specimen axis and the c axis at 293 K (i.e. the crystal orientation), a_{293} (c_{293}) is the length of the a (c) lattice parameters at 293 K, and n_a (n_c) is the number of a (c) lattice vectors going from one side of the crystal to the other in a direction parallel to the a (c) axis.

Similarly, in Figure 12(b)

$$tan \theta_{T} = n_{a}a_{T}/n_{c}c_{T}$$
 (A4.2).

where $\theta_{\rm T},~a_{\rm T},$ and $c_{\rm T}$ are the crystal orientation and lattice parameters at temperature T. Eliminating $n_{\rm a}/n_{\rm c}$ from Eqs. A4.1 and A4.2

$$\tan \theta_{T} = (c_{293}/a_{293})(\tan \theta_{293})(a_{T}/c_{T})$$

$$= \frac{(a_{T}/a_{293})}{(c_{T}/c_{293})} \tan \theta_{293}$$

$$= \frac{(L_{T}/L_{293})}{(L_{T}/L_{293})} \tan \theta_{293}.$$
(A4.3)

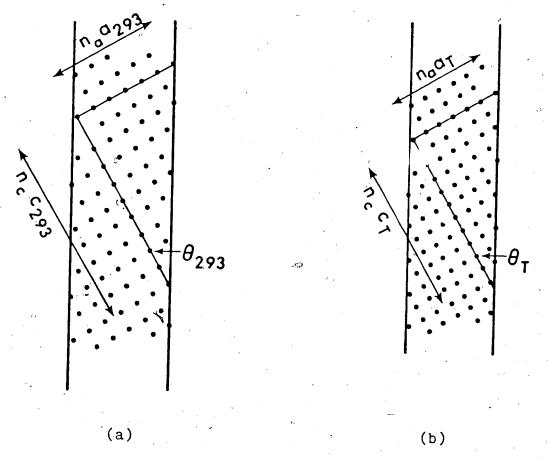


Fig. 12. Change of orientation due to anisotropic thermal contraction. The above diagrams represent a single crystal showing atomic s. es at (a) 293 K and (b) T < 293 K where there has been a decrease in c of 20% and a decrease in a of lo%.

Values of (L_T/L_293)| and (L_T/L_293), are given in Table 3 so that θ_T can be calculated knowing T and θ_{293} .